



Page i

**INTEGRATED CIRCUITS, SILICON MONOLITHIC,  
CMOS 8-STAGE SHIFT AND STORE BUS REGISTER,  
WITH SYNCHRONOUS SERIAL OUTPUTS  
AND 3-STATE PARALLEL OUTPUTS,  
BASED ON TYPE 4094B**

**ESCC Detail Specification No. 9306/026**

**ISSUE 1**

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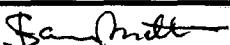
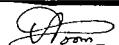
Pages 1 to 51

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**ESA/SCC Detail Specification No. 9306/026**



**space components  
coordination group**

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**SCC**

ESA/SCC Detail Specification  
No. 9306/026

PAGE 2  
ISSUE 3

## **DOCUMENTATION CHANGE NOTICE**

**SCC**ESA/SCC Detail Specification  
No. 9306/026PAGE 3  
ISSUE 3**TABLE OF CONTENTS**

	<u>Page</u>
<b>1. <u>GENERAL</u></b>	<b>5</b>
1.1 Scope	5
1.2 Component Type Variants	5
1.3 Maximum Ratings	5
1.4 Parameter Derating Information	5
1.5 Physical Dimensions	5
1.6 Pin Assignment	5
1.7 Truth Table	5
1.8 Circuit Schematic	5
1.9 Functional Diagram	5
1.10 Handling Precautions	5
1.11 Input Protection Network	5
<b>2. <u>APPLICABLE DOCUMENTS</u></b>	<b>17</b>
<b>3. <u>TERMS, DEFINITIONS, ABBREVIATIONS, SYMBOLS AND UNITS</u></b>	<b>17</b>
<b>4. <u>REQUIREMENTS</u></b>	<b>17</b>
4.1 General	17
4.2 Deviations from Generic Specification	17
4.2.1 Deviations from Special In-process Controls	17
4.2.2 Deviations from Final Production Tests	17
4.2.3 Deviations from Burn-in Tests	17
4.2.4 Deviations from Qualification Tests	17
4.2.5 Deviations from Lot Acceptance Tests	18
4.3 Mechanical Requirements	18
4.3.1 Dimension Check	18
4.3.2 Weight	18
4.4 Materials and Finishes	18
4.4.1 Case	18
4.4.2 Lead Material and Finish	18
4.5 Marking	18
4.5.1 General	18
4.5.2 Lead Identification	18
4.5.3 The SCC Component Number	19
4.5.4 Traceability Information	19
4.6 Electrical Measurements	19
4.6.1 Electrical Measurements at Room Temperature	19
4.6.2 Electrical Measurements at High and Low Temperatures	19
4.6.3 Circuits for Electrical Measurements	19
4.7 Burn-in Tests	19
4.7.1 Parameter Drift Values	19
4.7.2 Conditions for H.T.R.B. and Burn-in	19
4.7.3 Electrical Circuits for H.T.R.B. and Burn-in	19
4.8 Environmental and Endurance Tests	48
4.8.1 Electrical Measurements on Completion of Environmental Tests	48
4.8.2 Electrical Measurements at Intermediate Points during Endurance Tests	48
4.8.3 Electrical Measurements on Completion of Endurance Tests	48
4.8.4 Conditions for Operating Life Test	48
4.8.5 Electrical Circuits for Operating Life Tests	48
4.8.6 Conditions for High Temperature Storage Test	48

**SCC**

Page

**TABLES**

1(a)	Type Variants	6
1(b)	Maximum Ratings	6
2	Electrical Measurements at Room Temperature, d.c. Parameters	20
	Electrical Measurements at Room Temperature, a.c. Parameters	24
3(a)	Electrical Measurements at High Temperature	27
3(b)	Electrical Measurements at Low Temperature	31
4	Parameter Drift Values	43
5(a)	Conditions for Burn-in High Temperature Reverse Bias, N-Channels	44
5(b)	Conditions for Burn-in High Temperature Reverse Bias, P-Channels	44
5(c)	Conditions for Burn-in Dynamic	45
6	Electrical Measurements on Completion of Environmental Tests and at Intermediate Points and on Completion of Endurance Testing	49

**FIGURES**

1	Not applicable	
2	Physical Dimensions	7
3(a)	Pin Assignment	13
3(b)	Truth Table	14
3(c)	Circuit Schematic	15
3(d)	Functional Diagram	16
3(e)	Input Protection Network	16
4	Circuits for Electrical Measurements	35
5(a)	Electrical Circuit for Burn-in High Temperature Reverse Bias, N-Channels	46
5(b)	Electrical Circuit for Burn-in High Temperature Reverse Bias, P-Channels	46
5(c)	Electrical Circuit for Burn-in Dynamic	47

**APPENDICES (Applicable to specific Manufacturers only)**

'A'	Agreed Deviations for STMicroelectronics (F)	51
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## 1. GENERAL

### 1.1 SCOPE

This specification details the ratings, physical and electrical characteristics, test and inspection data for a silicon monolithic, CMOS 8-Stage Shift and Store Bus Register, with fully buffered Synchronous Serial Outputs and 3-State Parallel Outputs, based on Type 4094B. It shall be read in conjunction with ESA/SCC Generic Specification No. 9000, the requirements of which are supplemented herein.

### 1.2 COMPONENT TYPE VARIANTS

Variants of the basic type integrated circuits specified herein, which are also covered by this specification, are given in Table 1(a).

### 1.3 MAXIMUM RATINGS

The maximum ratings, which shall not be exceeded at any time during use or storage, applicable to the integrated circuits specified herein, are as scheduled in Table 1(b).

Maximum ratings shall only be exceeded during testing to the extent specified in this specification and when stipulated in Test Methods and Procedures of the applicable ESA/SCC Generic Specification.

### 1.4 PARAMETER DERATING INFORMATION (FIGURE 1)

Not applicable.

### 1.5 PHYSICAL DIMENSIONS

The physical dimensions of the integrated circuits specified herein are shown in Figure 2.

### 1.6 PIN ASSIGNMENT

As per Figure 3(a).

### 1.7 TRUTH TABLE

As per Figure 3(b).

### 1.8 CIRCUIT SCHEMATIC

As per Figure 3(c).

### 1.9 FUNCTIONAL DIAGRAM

As per Figure 3(d).

### 1.10 HANDLING PRECAUTIONS

These devices are susceptible to damage by electrostatic discharge. Therefore, suitable precautions shall be employed for protection during all phases of manufacture, testing, packaging, shipment and any handling. These components are Categorised as Class 1 with a Minimum Critical Path Failure Voltage of 400 Volts.

### 1.11 INPUT PROTECTION NETWORK

Double diode protection shall be incorporated into each input as shown in Figure 3(e).



SCC

ESA/SCC Detail Specification

No. 9306/026

PAGE 6

ISSUE 3

**TABLE 1(a) - TYPE VARIANTS**

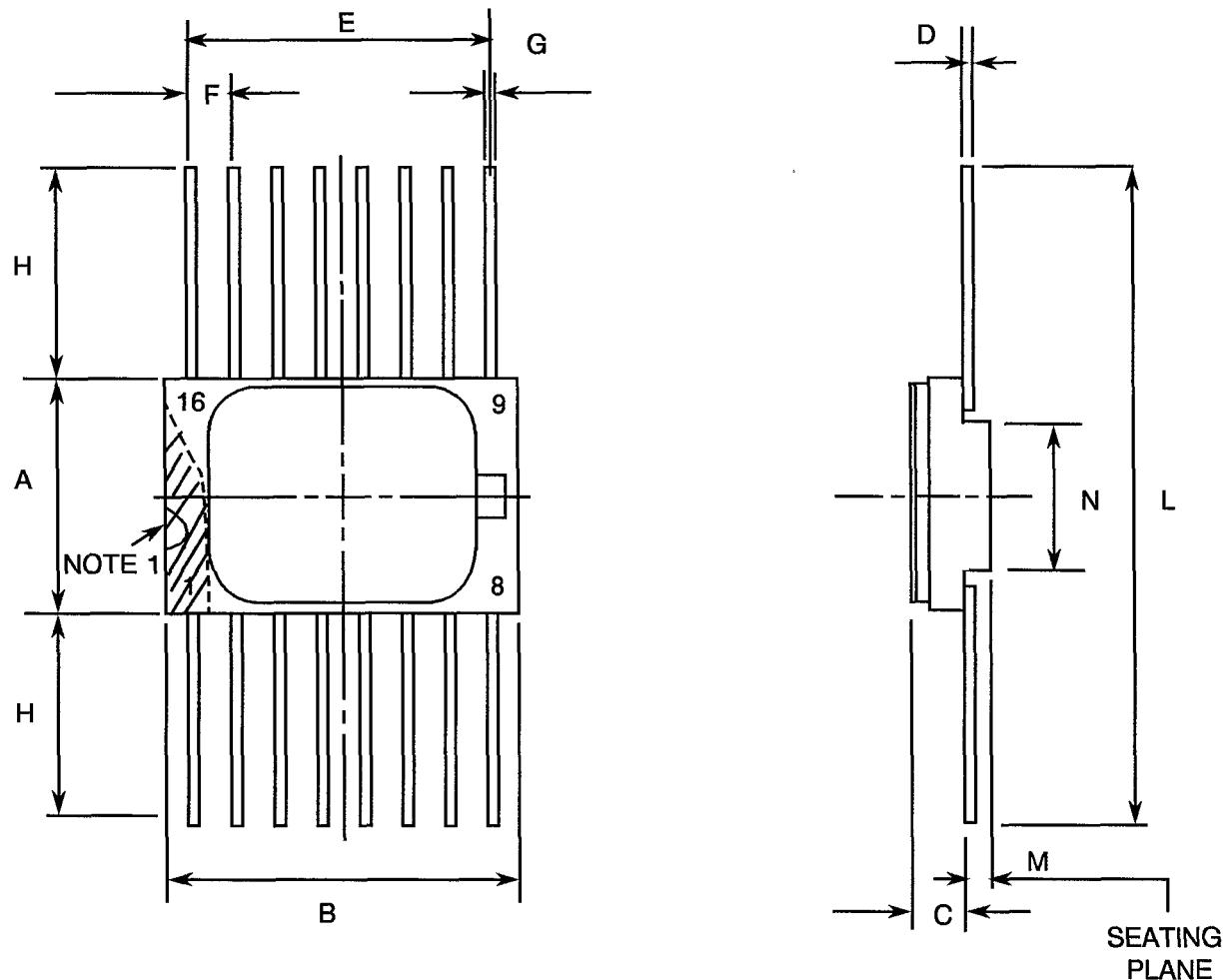
VARIANT	CASE	FIGURE	LEAD MATERIAL AND/OR FINISH
01	FLAT	2(a)	G2 or G8
02	FLAT	2(a)	G4
03	D.I.L.	2(b)	G2 or G8
04	D.I.L.	2(b)	G4
07	CHIP CARRIER	2(c)	2
08	D.I.L.	2(d)	G2
09	D.I.L.	2(d)	G4
10	SO CERAMIC	2(e)	G2
11	SO CERAMIC	2(e)	G4

**TABLE 1(b) - MAXIMUM RATINGS**

NO.	CHARACTERISTICS	SYMBOL	MAXIMUM RATINGS	UNIT	REMARKS
1	Supply Voltage	$V_{DD}$	-0.5 to + 18	V	Note 1
2	Input Voltage	$V_{IN}$	-0.5 to $V_{DD} + 0.5$	V	Note 2 Power on
3	D.C. Input Current	$\pm I_{IN}$	10	mA	-
4	D.C. Output Current	$\pm I_O$	10	mA	Note 3
5	Device Dissipation	$P_D$	200	mWdc	Per Package
6	Output Dissipation	$P_{D\text{SO}}$	100	mWdc	Note 4
7	Operating Temperature Range	$T_{op}$	-55 to + 125	°C	-
8	Storage Temperature Range	$T_{stg}$	-65 to + 150	°C	-
9	Soldering Temperature For FP and DIP For CCP	$T_{sol}$	+ 300 + 245	°C	Note 5 Note 6

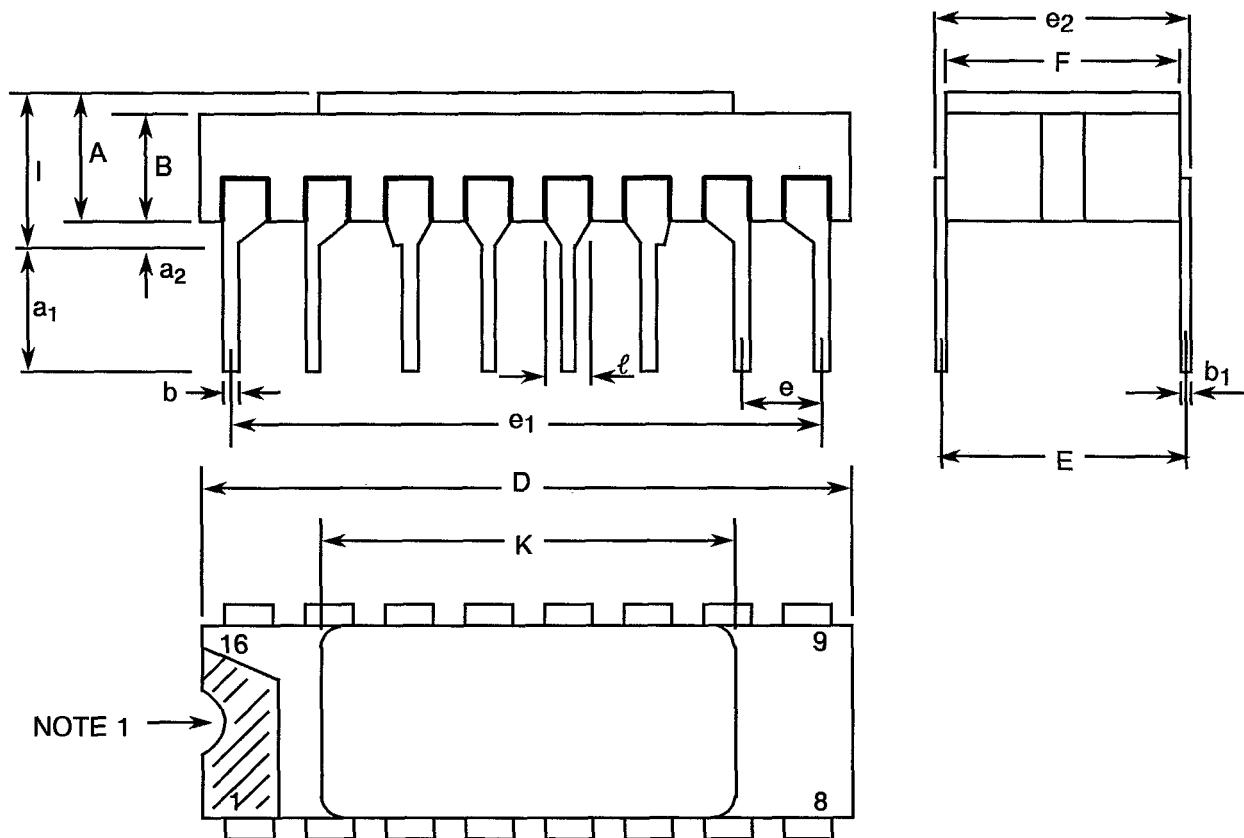
**NOTES**

1. Device is functional from + 3V to + 15V with reference to  $V_{SS}$ .
2.  $V_{DD} + 0.5V$  should not exceed + 18V.
3. The maximum output current of any single output.
4. The maximum power dissipation of any single output.
5. Duration 10 seconds maximum at a distance of not less than 1.5mm from the device body and the same lead shall not be resoldered until 3 minutes have elapsed.
6. Duration 30 seconds maximum and the same terminal shall not be resoldered until 3 minutes have elapsed.

**FIGURE 2 - PHYSICAL DIMENSIONS****FIGURE 2(a) - FLAT PACKAGE, 16-PIN**

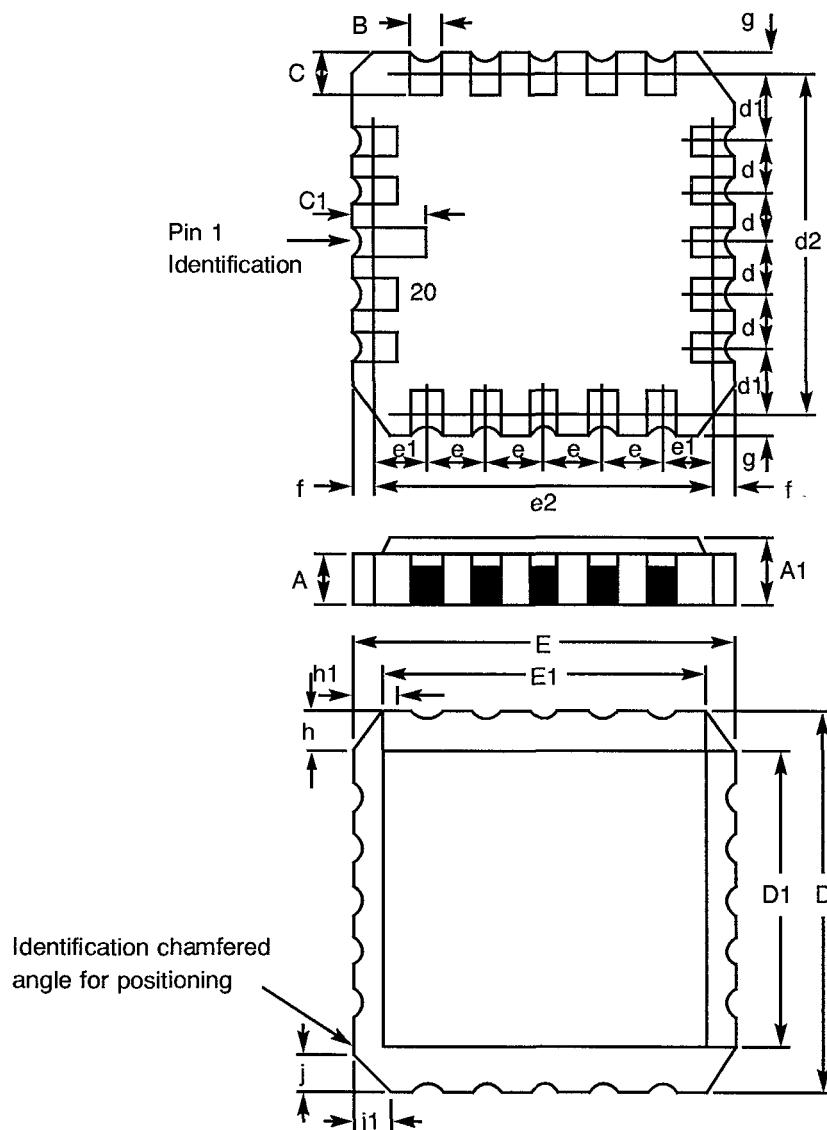
SYMBOL	MILLIMETRES		NOTES
	MIN	MAX	
A	6.75	7.06	
B	9.76	10.14	
C	1.49	1.95	
D	0.102	0.152	3
E	8.76	9.01	
F	1.27	TYPICAL	4
G	0.38	0.48	3
H	6.0	-	3
L	18.75	22.0	
M	0.33	0.43	
N	4.31	TYPICAL	

**NOTES:** See Page 12.

FIGURE 2 - PHYSICAL DIMENSIONS (CONTINUED)FIGURE 2(b) - DUAL-IN-LINE PACKAGE, 16-PIN

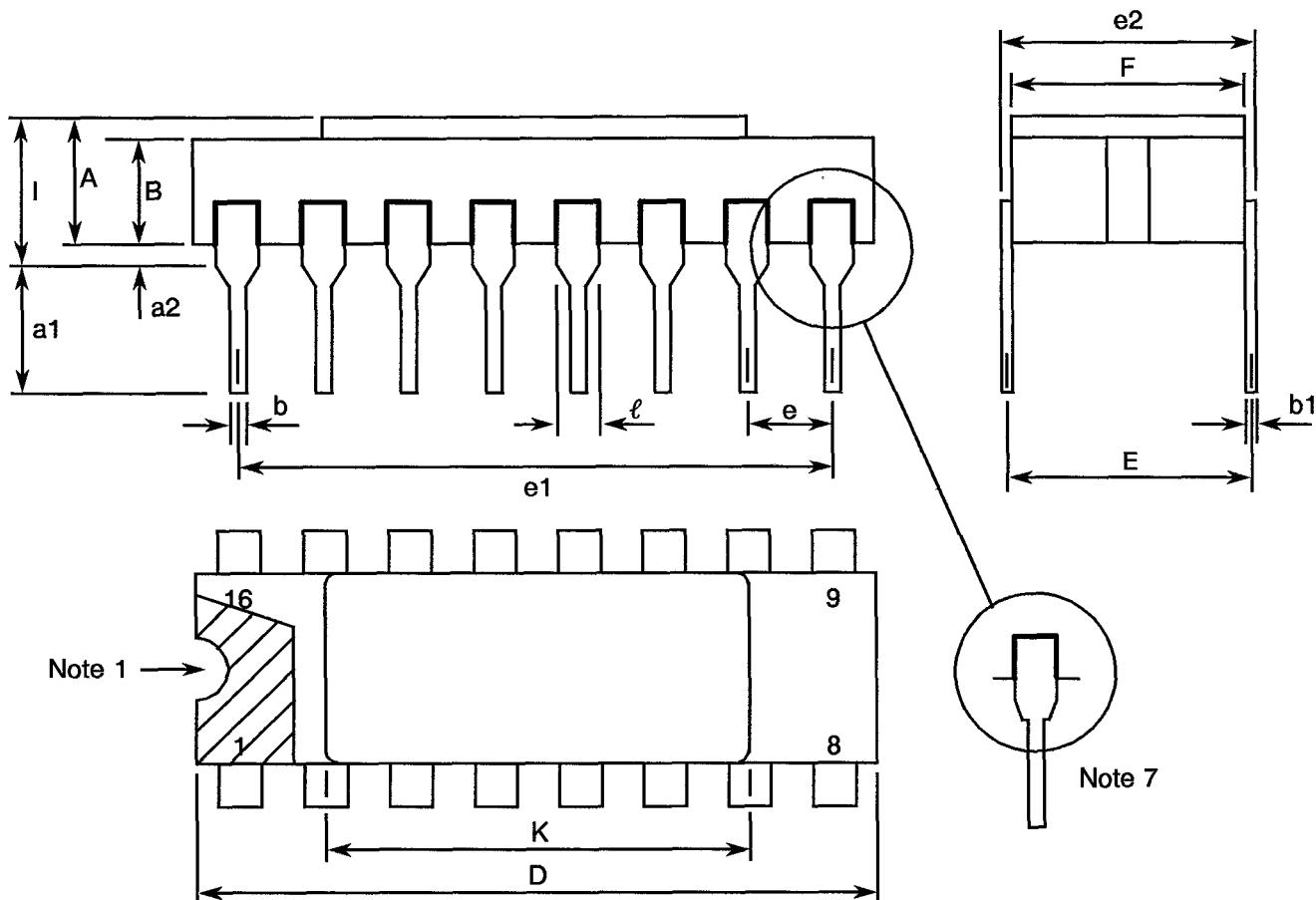
SYMBOL	MILLIMETRES		NOTES
	MIN	MAX	
A	2.10	2.54	
$a_1$	3.0	3.7	
$a_2$	0.63	1.14	2
B	1.82	2.23	
b	0.40	0.50	3
$b_1$	0.20	0.30	3
D	18.79	19.20	
E	7.36	7.87	
e	2.41	2.67	4
$e_1$	17.65	17.90	
$e_2$	7.62	8.12	
F	7.11	7.62	
I	-	3.70	
K	10.90	12.10	
$\ell$	1.27 TYPICAL		

NOTES: See Page 12.

**FIGURE 2 - PHYSICAL DIMENSIONS (CONTINUED)****FIGURE 2(c) - CHIP CARRIER - 20-Terminal**

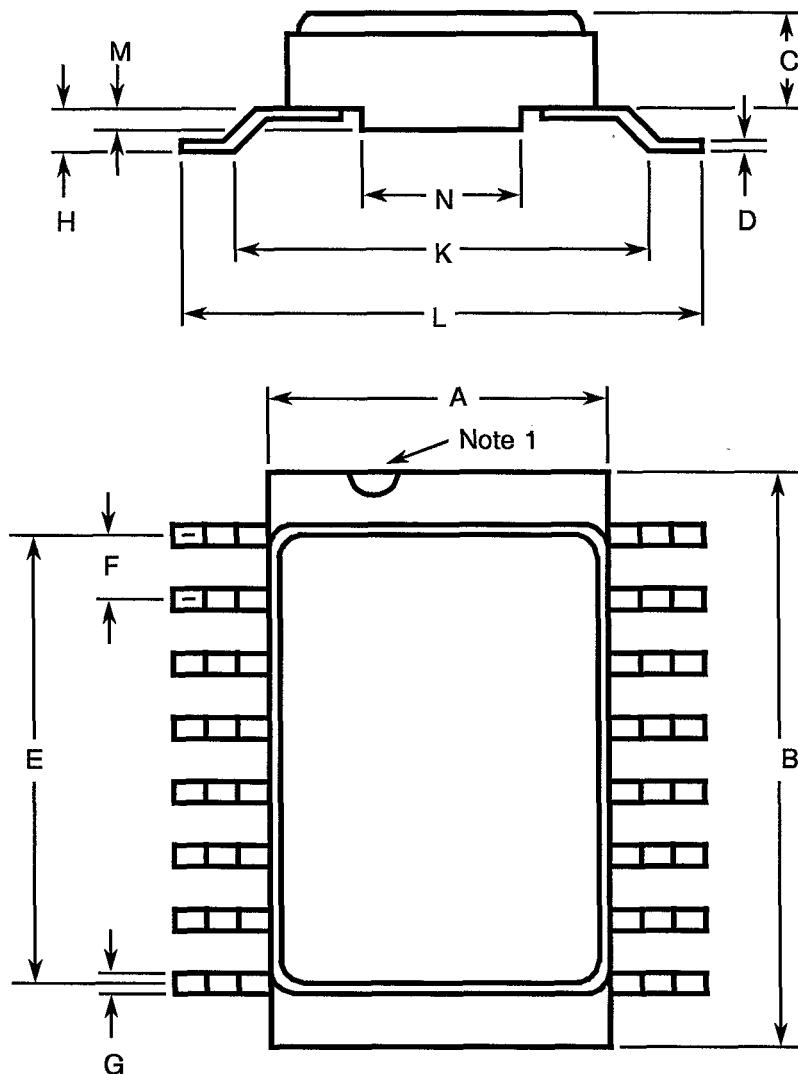
DIMENSIONS	MILLIMETRES		NOTES
	MIN	MAX	
A	1.14	1.95	
A <sub>1</sub>	1.63	2.36	
B	0.55	0.72	
C	1.06	1.47	3
C <sub>1</sub>	1.91	2.41	3
D	8.67	9.09	
D <sub>1</sub>	7.21	7.52	
d, d <sub>1</sub>	1.27	TYPICAL	
d <sub>2</sub>	7.62	TYPICAL	4
E	8.67	9.09	
E <sub>1</sub>	7.21	7.52	
e, e <sub>1</sub>	1.27	TYPICAL	
e <sub>2</sub>	7.62	TYPICAL	4
f, g	-	0.76	
h, h <sub>1</sub>	1.01	TYPICAL	6
j, j <sub>1</sub>	0.51	TYPICAL	5

**NOTES:** See Page 12.

**FIGURE 2 - PHYSICAL DIMENSIONS (CONTINUED)****FIGURE 2(d) - DUAL-IN-LINE PACKAGE, 16-PIN**

SYMBOL	MILLIMETRES		NOTES
	MIN	MAX	
A	2.10	2.71	
a1	3.00	3.70	
a2	0.63	1.14	3
B	1.82	2.39	
b	0.40	0.50	8
b1	0.20	0.30	8
D	20.06	20.58	
E	7.36	7.87	
e	2.54 TYPICAL		6, 9
e1	17.65	17.90	
e2	7.62	8.12	
F	7.29	7.70	
I	-	3.83	
K	10.90	12.10	
l	1.14	1.50	8

**NOTES:** See Page 12.

**FIGURE 2 - PHYSICAL DIMENSIONS (CONTINUED)****FIGURE 2(e) - SMALL OUTLINE CERAMIC PACKAGE, 16-PIN**

SYMBOL	MILLIMETRES		NOTES
	MIN.	MAX.	
A	6.75	7.06	
B	9.76	10.14	
C	1.49	1.95	
D	0.102	0.152	3
E	8.76	9.01	
F	1.27 TYPICAL		4
G	0.38	0.48	3
H	0.60	0.90	3
K	9.00 TYPICAL		
L	10	10.65	
M	0.33	0.43	
N	4.31 TYPICAL		

**NOTES:** See Page 12.

**SCC**

ESA/SCC Detail Specification  
No. 9306/026

PAGE 12

ISSUE 3

**FIGURE 2 - PHYSICAL DIMENSIONS (CONTINUED)****NOTES TO FIGURES 2(a) TO 2(e) INCLUSIVE**

1. Index area: a notch, letter or dot shall be located adjacent to Pin 1 and shall be within the shaded area shown. For chip carrier packages the index shall be as defined in Figure 2(c).
2. The dimension shall be measured from the seating plane to the base plane.
3. All leads or terminals.
4. 16 pin packages : 14 spaces  
20 terminal packages : 12 spaces
5. Index corner only.
6. Three non-index corners.
7. For all pins, either pin shape may be supplied.

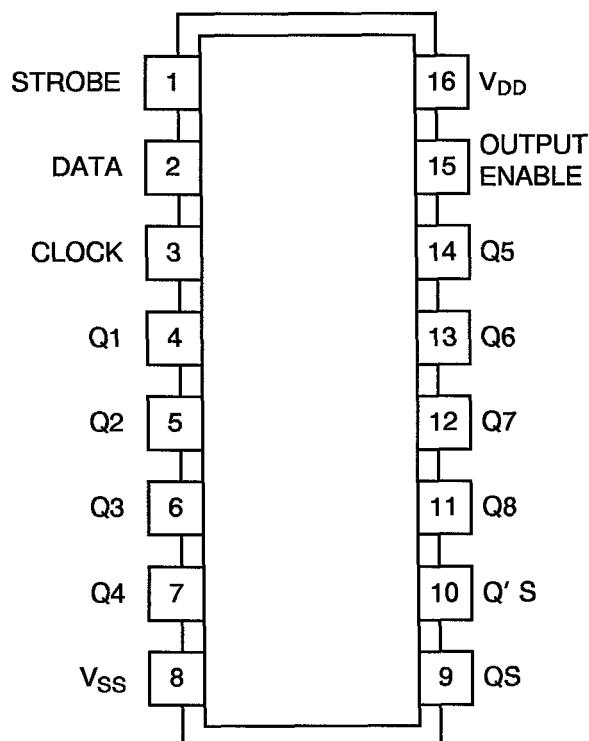
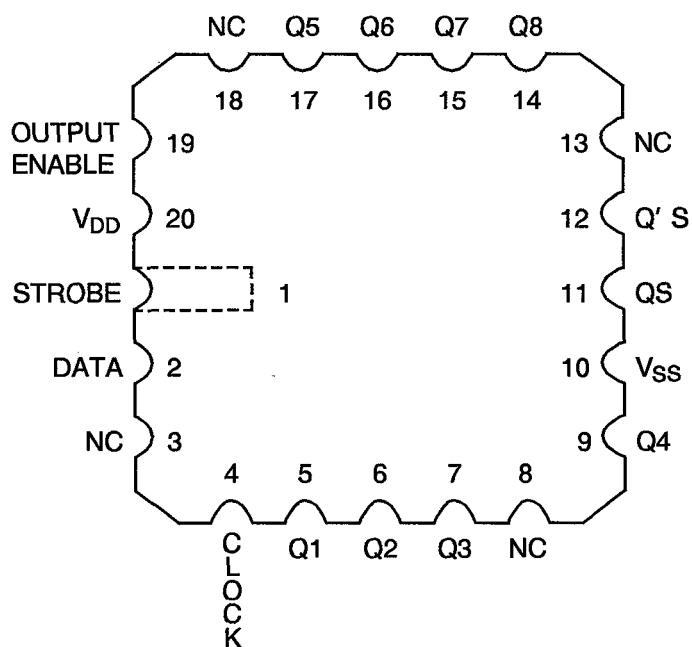
**SCC**

ESA/SCC Detail Specification

No. 9306/026

PAGE 13

ISSUE 3

**FIGURE 3(a) - PIN ASSIGNMENT****DUAL-IN-LINE, SO AND FLAT PACKAGES****CHIP CARRIER PACKAGE****(TOP VIEW)****(TOP VIEW)****FLAT PACKAGE, SO AND DUAL-IN-LINE TO CHIP CARRIER PIN ASSIGNMENT**FLAT PACKAGE, SO AND  
DUAL-IN-LINE PIN OUTS

1 2 3 4 5 6 7 8 9 10 11 12 13 14 15 16

CHIP CARRIER PIN OUTS

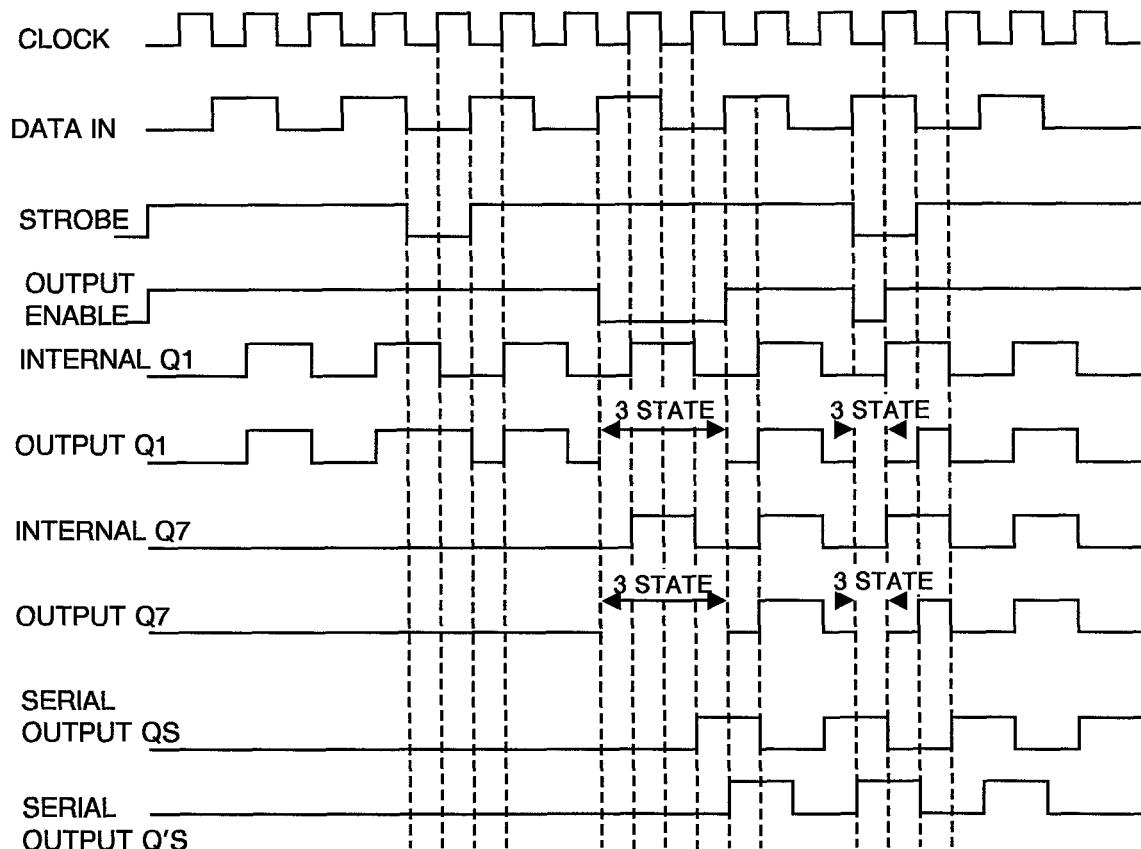
1 2 4 5 6 7 9 10 11 12 14 15 16 17 19 20

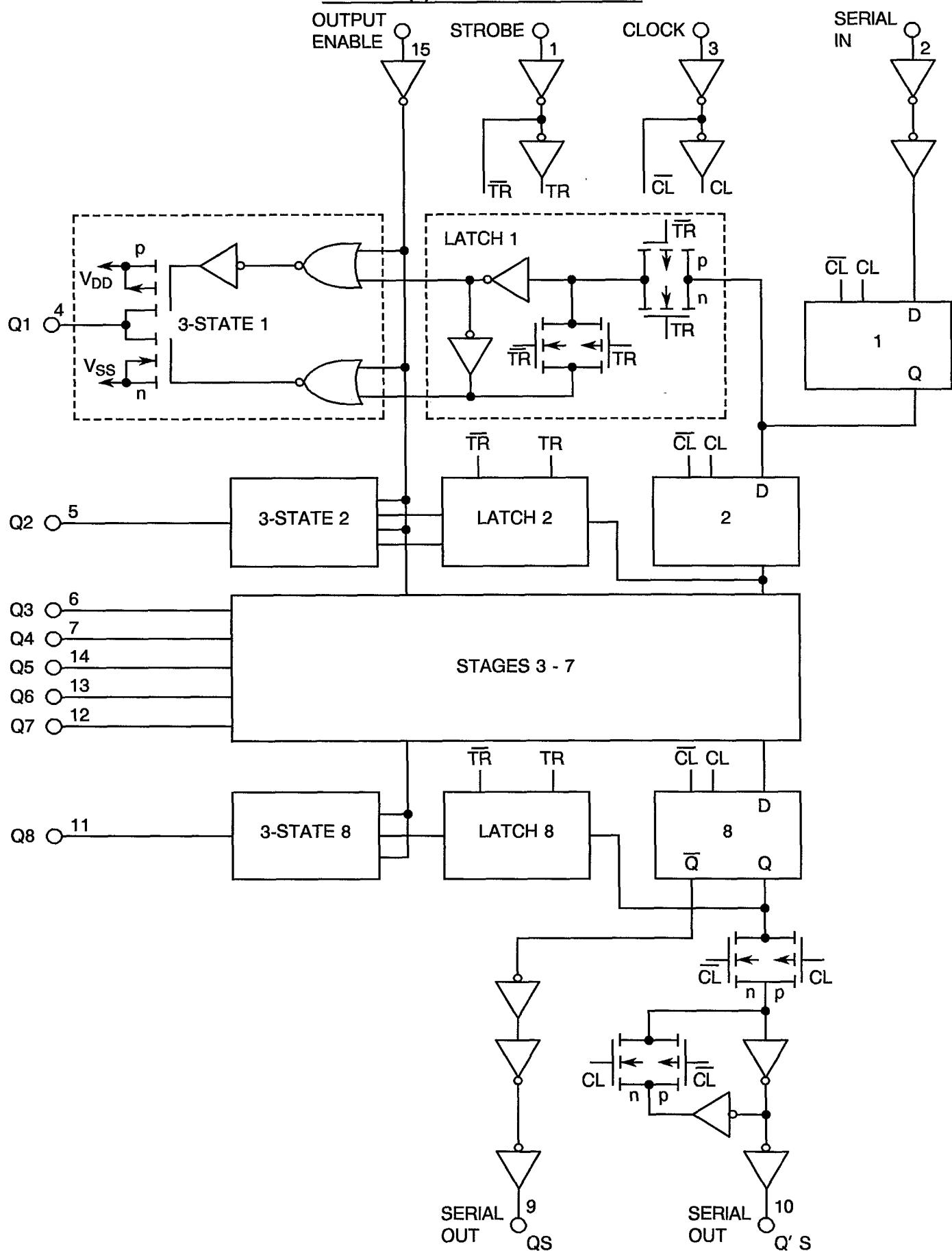
FIGURE 3(b) - TRUTH TABLE

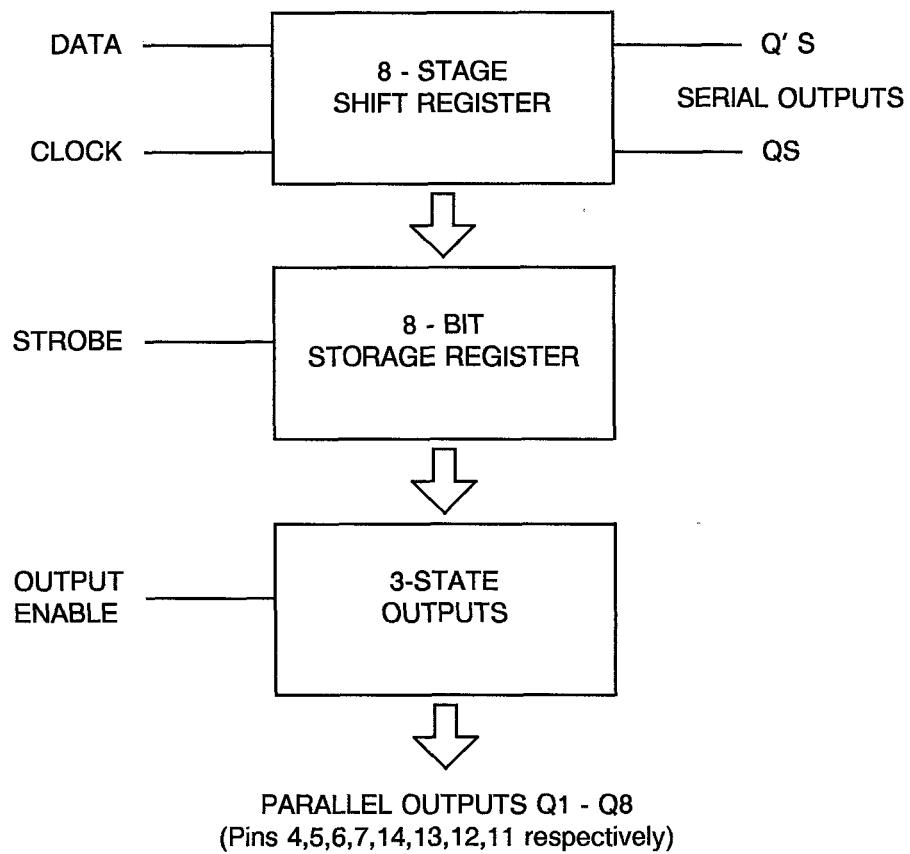
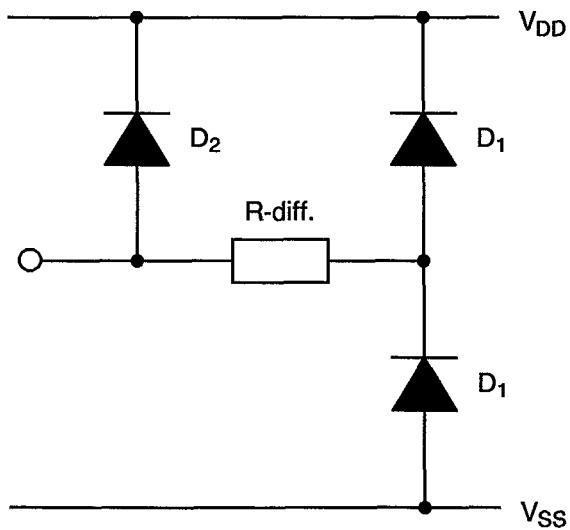
CL	OUTPUT ENABLE	STROBE	DATA	PARALLEL OUTPUTS		SERIAL OUTPUTS	
				Q1	QN	QS (1)	Q' S
[	L	X	X	OC	OC	(Q7)	NC
]	L	X	X	OC	OC	NC	(Q7)
[	H	L	X	NC	NC	(Q7)	NC
]	H	H	L	L	QN-1	(Q7)	NC
[	H	H	H	H	QN-1	(Q7)	NC
]	H	H	H	NC	NC	NC	(Q7)

**NOTES**

1. At the positive clock edge, information in the 7th Shift Register Stage (internal) is transferred to the 8th Register Stage and the QS output.
2. Logic Level Definitions: L = Low Level, H = High Level, X = Don't Care, OC = Open Circuit.
3. [ = Positive-going transition, ] = Negative-going transition.

TIMING DIAGRAM

**FIGURE 3(c) - CIRCUIT SCHEMATIC**

**FIGURE 3(d) - FUNCTIONAL DIAGRAM****FIGURE 3(e) - INPUT PROTECTION NETWORK**



## 2. APPLICABLE DOCUMENTS

The following documents form part of this specification and shall be read in conjunction with it:-

- (a) ESA/SCC Generic Specification No. 9000 for Integrated Circuits.
- (b) MIL-STD-883, Test Methods and Procedures for Micro-electronics.

## 3. TERMS, DEFINITIONS, ABBREVIATIONS, SYMBOLS AND UNITS

For the purpose of this specification, the terms, definitions, abbreviations, symbols and units specified in ESA/SCC Basic Specification No. 21300 shall apply. In addition, the following abbreviations are used:

V <sub>IC</sub>	= Input Clamp Voltage
P <sub>D50</sub>	= Single Output Power Dissipation
CKT	= Circuit
I <sub>OZ</sub>	= Output Leakage Current Third State
t <sub>PHZ</sub>	= Propagation Delay, High Output to High Impedance
t <sub>PZH</sub>	= Propagation Delay, High Impedance to High Output
t <sub>PLZ</sub>	= Propagation Delay, Low Output to High Impedance
t <sub>PZL</sub>	= Propagation Delay, High Impedance to Low Output

## 4. REQUIREMENTS

### 4.1 GENERAL

The complete requirements for procurement of the integrated circuits specified herein shall be as stated in this specification and ESA/SCC Generic Specification No. 9000 for Integrated Circuits. Deviations from the Generic Specification, applicable to this specification only, are listed in Para. 4.2.

Deviations from the applicable Generic Specification and this Detail Specification, formally agreed with specific Manufacturers on the basis that the alternative requirements are equivalent to the ESA/SCC requirement and do not affect the components' reliability, are listed in the appendices attached to this specification.

### 4.2 DEVIATIONS FROM GENERIC SPECIFICATION

#### 4.2.1 Deviations from Special In-process Controls

None.

#### 4.2.2 Deviations from Final Production Tests (Chart II)

None.

#### 4.2.3 Deviations from Burn-in Tests (Chart III)

##### 4.2.3.1 Deviations from High Temperature Reverse Bias (H.T.R.B.)

Prior to operating power burn-in, a high temperature reverse bias (H.T.R.B.) screen at +125°C shall be added for the N-Channel and then for the P-Channel in accordance with Tables 5(a) and 5(b) of this specification. Each exposure to H.T.R.B. shall be 72 hours and Table 4 Parameter Drift Values shall be applied at 0 and 144 hours.

#### 4.2.4 Deviations from Qualification Tests (Chart IV)

None.

**SCC**ESA/SCC Detail Specification  
No. 9306/026

PAGE 18

ISSUE 3

**4.2.5 Deviations from Lot Acceptance Tests (Chart V)**

None.

**4.3 MECHANICAL REQUIREMENTS****4.3.1 Dimension Check**

The dimensions of the integrated circuits specified herein shall be checked. They shall conform to those shown in Figure 2.

**4.3.2 Weight**

The maximum weight of the integrated circuits specified herein shall be 1.5 grammes for the dual-in-line package, 0.6 grammes for the flat and SO packages and 0.52 grammes for the chip carrier package.

**4.4 MATERIALS AND FINISHES**

The materials and finishes shall be as specified herein. Where a definite material is not specified, a material which will enable the integrated circuits specified herein to meet the performance requirements of this specification shall be used. Acceptance or approval of any constituent material does not guarantee acceptance of the finished product.

**4.4.1 Case**

The case shall be hermetically sealed and have a metal body with hard glass seals or a ceramic body and the lids shall be welded, brazed or preform-soldered.

**4.4.2 Lead Material and Finish**

For dual-in-line and flat packages, the material shall be Type 'G' with either Type '4' or Type '2 or 8' finish in accordance with ESA/SCC Basic Specification No. 23500. For chip carrier packages the finish shall be Type '2' in accordance with ESA/SCC Basic Specification No. 23500. For SO ceramic packages, the material shall be Type 'G' with either Type '2' or Type '4' finish in accordance with ESA/SCC Basic Specification No. 23500. (See Table 1(a) for Type Variants).

**4.5 MARKING****4.5.1 General**

The marking of all components delivered to this specification shall be in accordance with the requirements of ESA/SCC Basic Specification No. 21700. Each component shall be marked in respect of:-

- (a) Lead Identification.
- (b) The SCC Component Number.
- (c) Traceability Information.

**4.5.2 Lead Identification**

For dual-in-line, flat and SO packages, an index shall be located at the top of the package in the position defined in Note 1 to Figure 2 or, alternatively, a tab may be used to identify Pin No. 1. The pin numbering must be read with the index or tab on the left-hand side. For chip carrier packages, the index shall be as defined by Figure 2(c).



#### 4.5.3 The SCC Component Number

Each component shall bear the SCC Component Number which shall be constituted and marked as follows:

Detail Specification Number	930602601B
Type Variant, as applicable	
Testing Level (B or C, as appropriate)	

#### 4.5.4 Traceability Information

Each component shall be marked in respect of traceability information in accordance with the requirements of ESA/SCC Basic Specification No. 21700.

### 4.6 ELECTRICAL MEASUREMENTS

#### 4.6.1 Electrical Measurements at Room Temperature

The parameters to be measured in respect of electrical characteristics are scheduled in Table 2. Unless otherwise specified, the measurements shall be performed at  $T_{amb} = +22 \pm 3^{\circ}\text{C}$ .

#### 4.6.2 Electrical Measurements at High and Low Temperatures

The parameters to be measured at high and low temperatures are scheduled in Table 3. The measurements shall be performed at  $T_{amb} = +125(+0-5)^{\circ}\text{C}$  and  $-55(+5-0)^{\circ}\text{C}$  respectively.

#### 4.6.3 Circuits for Electrical Measurements

Circuits and functional test sequence for use in performing electrical measurements listed in Tables 2 and 3 of this specification are shown in Figure 4.

### 4.7 BURN-IN TESTS

#### 4.7.1 Parameter Drift Values

The parameter drift values applicable to burn-in are specified in Table 4 of this specification. Unless otherwise stated, measurements shall be performed at  $+22 \pm 3^{\circ}\text{C}$ . The parameter drift values ( $\Delta$ ) applicable to the parameters scheduled, shall not be exceeded. In addition to these drift value requirements, the appropriate limit value specified for a given parameter in Table 2 shall not be exceeded.

#### 4.7.2 Conditions for H.T.R.B. and Burn-in

The requirements for H.T.R.B. and Burn-in are specified in Section 7 of ESA/SCC Generic Specification No. 9000. The conditions for H.T.R.B. and Burn-in shall be as specified in Tables 5(a), 5(b) and 5(c) of this specification.

#### 4.7.3 Electrical Circuits for H.T.R.B. and Burn-in

Circuits for use in performing the H.T.R.B. and Burn-in tests are shown in Figures 5(a), 5(b) and 5(c) of this specification.



SCC

ESA/SCC Detail Specification  
No. 9306/026

PAGE 20  
ISSUE 3

**TABLE 2 - ELECTRICAL MEASUREMENTS AT ROOM TEMPERATURE - d.c. PARAMETERS**

NO.	CHARACTERISTICS	SYMBOL	TEST METHOD MIL-STD 883	TEST FIG.	TEST CONDITIONS (PINS UNDER TEST D/F = DIP AND FP C = CCP)	LIMITS		UNIT
						MIN	MAX	
1	Functional Test	-	-	4(a)	Verify Truth Table without Load. $V_{DD} = 3\text{Vdc}$ , $V_{SS} = 0\text{Vdc}$ Notes 1 and 2	-	-	-
2	Functional Test	-	-	4(a)	Verify Truth Table without Load. $V_{DD} = 15\text{Vdc}$ , $V_{SS} = 0\text{Vdc}$ Notes 1 and 2	-	-	-
3 to 5	Quiescent Current	$I_{DD}$	3005	4(b)	$V_{IL} = 0\text{Vdc}$ , $V_{IH} = 15\text{Vdc}$ $V_{DD} = 15\text{Vdc}$ , $V_{SS} = 0\text{Vdc}$ (Pin D/F 16) (Pin C 20)	-	1.0	$\mu\text{A}$
6 to 9	Input Current Low Level	$I_{IL}$	3009	4(c)	$V_{IN} (\text{Under Test}) = 0\text{Vdc}$ $V_{IN} (\text{All Other Inputs}) = 15\text{Vdc}$ $V_{DD} = 15\text{Vdc}$ , $V_{SS} = 0\text{Vdc}$ (Pins D/F 1-2-3-15) (Pins C 1-2-4-19)	-	-50	nA
10 to 13	Input Current High Level	$I_{IH}$	3010	4(d)	$V_{IN} (\text{Under Test}) = 15\text{Vdc}$ $V_{IN} (\text{All Other Inputs}) = 0\text{Vdc}$ $V_{DD} = 15\text{Vdc}$ , $V_{SS} = 0\text{Vdc}$ (Pins D/F 1-2-3-15) (Pins C 1-2-4-19)	-	50	nA
14 to 23	Output Voltage Low Level	$V_{OL}$	3007	4(e)	$V_{IN} (\text{Data}) = 0\text{Vdc}$ Clock = Pulse Generator $V_{IN} (\text{All Other Inputs}) = 15\text{Vdc}$ $V_{OUT} = \text{Open}$ $V_{DD} = 15\text{Vdc}$ , $V_{SS} = 0\text{Vdc}$ Note 3 (Pins D/F 4-5-6-7-9-10-11-12-13-14) (Pins C 5-6-7-9-11-12-14-15-16-17)	-	0.05	V

**NOTES:** See Page 26.



SCC

ESA/SCC Detail Specification

No. 9306/026

PAGE 21

ISSUE 3

TABLE 2 - ELECTRICAL MEASUREMENTS AT ROOM TEMPERATURE - d.c. PARAMETERS (CONT'D)

NO.	CHARACTERISTICS	SYMBOL	TEST METHOD MIL-STD 883	TEST FIG.	TEST CONDITIONS (PINS UNDER TEST D/F = DIP AND FP C = CCP)	LIMITS		UNIT
						MIN	MAX	
24 to 33	Output Voltage Low Level	$V_{OH}$	3006	4(f)	$V_{IN}$ (Enable) = 15Vdc Clock = Pulse Generator $V_{IN}$ (All Other Inputs) = 15Vdc $V_{OUT}$ = Open $V_{DD}$ = 15Vdc, $V_{SS}$ = 0Vdc Note 3 (Pins D/F 4-5-6-7-9-10-11- 12-13-14) (Pins C 5-6-7-9-11-12-14- 15-16-17)	14.95	-	V
34 to 43	Output Drive Current N-Channel	$I_{OL1}$	-	4(g)	$V_{IN}$ (Data) = 0Vdc Clock = Pulse Generator $V_{IN}$ (All Other Inputs) = 5Vdc $V_{OUT}$ = 0.4Vdc $V_{DD}$ = 5Vdc, $V_{SS}$ = 0Vdc Notes 3 and 4 (Pins D/F 4-5-6-7-9-10-11- 12-13-14) (Pins C 6-7-9-10-14-15- 16-17-19-20)	0.51	-	mA
44 to 53	Output Drive Current N-Channel	$I_{OL2}$	-	4(g)	$V_{IN}$ (Data) = 0Vdc Clock = Pulse Generator $V_{IN}$ (All Other Inputs) = 15Vdc $V_{OUT}$ = 1.5Vdc $V_{DD}$ = 15Vdc, $V_{SS}$ = 0Vdc Notes 3 and 4 (Pins D/F 4-5-6-7-9-10-11- 12-13-14) (Pins C 6-7-9-10-14-15- 16-17-19-20)	3.4	-	mA
54 to 63	Output Drive Current P-Channel	$I_{OH1}$	-	4(h)	$V_{IN}$ (Enable) = 5Vdc Clock = Pulse Generator $V_{IN}$ (All Other Inputs) = 5Vdc $V_{OUT}$ = 4.6Vdc $V_{DD}$ = 5Vdc, $V_{SS}$ = 0Vdc Notes 3 and 4 (Pins D/F 4-5-6-7-9-10-11- 12-13-14) (Pins C 6-7-9-10-14-15- 16-17-19-20)	-0.51	-	mA

**NOTES:** See Page 26.



SCC

ESA/SCC Detail Specification

No. 9306/026

PAGE 22

ISSUE 3

TABLE 2 - ELECTRICAL MEASUREMENTS AT ROOM TEMPERATURE - d.c. PARAMETERS (CONT'D)

NO.	CHARACTERISTICS	SYMBOL	TEST METHOD MIL-STD 883	TEST FIG.	TEST CONDITIONS (PINS UNDER TEST D/F = DIP AND FP C = CCP)	LIMITS		UNIT
						MIN	MAX	
64 to 73	Output Drive Current P-Channel	$I_{OH2}$	-	4(h)	$V_{IN}$ (Enable) = 15Vdc Clock = Pulse Generator $V_{IN}$ (All Other Inputs) = 15Vdc $V_{OUT}$ = 13.5Vdc $V_{DD}$ = 15Vdc, $V_{SS}$ = 0Vdc Notes 3 and 4 (Pins D/F 4-5-6-7-9-10-11-12-13-14) (Pins C 6-7-9-10-14-15-16-17-19-20)	-3.4	-	mA
74 to 81	Output Leakage Current Third State (1)	$I_{OZ1}$	-	4(i)	$V_{IN}$ (Strobe and Data) = 15Vdc Clock = Pulse Generator $V_{IN}$ (Enable) = 0Vdc $V_{OUT}$ = 15Vdc $V_{DD}$ = 15Vdc, $V_{SS}$ = 0Vdc (Pins D/F 4-5-6-7-11-12-13-14) (Pins C 5-6-7-9-14-15-16-17)	-	0.4	$\mu A$
82 to 89	Output Leakage Current Third State (2)	$I_{OZ2}$	-	4(i)	$V_{IN}$ (Strobe and Data) = 15Vdc Clock = Pulse Generator $V_{IN}$ (Enable) = 0Vdc $V_{OUT}$ = 0Vdc $V_{DD}$ = 15Vdc, $V_{SS}$ = 0Vdc (Pins D/F 4-5-6-7-11-12-13-14) (Pins C 5-6-7-9-14-15-16-17)	-	-0.4	$\mu A$
90	Input Voltage Low Level (Noise Immunity) (Functional Test)	$V_{IL1}$	-	4(a)	$V_{IL} = 1.5Vdc$ $V_{IH} = 3.5Vdc$ $V_{DD} = 5Vdc, V_{SS} = 0Vdc$ Note 5 (Pins D/F 4-5-6-7-9-10-11-12-13-14) (Pins C 5-6-7-9-11-12-14-15-16-17)	4.5	-	V
	Input Voltage High Level (Noise Immunity) (Functional Test)	$V_{IH1}$			-	0.5		

NOTES: See Page 26.



SCC

ESA/SCC Detail Specification

No. 9306/026

PAGE 23

ISSUE 3

**TABLE 2 - ELECTRICAL MEASUREMENTS AT ROOM TEMPERATURE - d.c. PARAMETERS (CONT'D)**

NO.	CHARACTERISTICS	SYMBOL	TEST METHOD MIL-STD 883	TEST FIG.	TEST CONDITIONS (PINS UNDER TEST D/F = DIP AND FP C = CCP)	LIMITS		UNIT
						MIN	MAX	
91	Input Voltage Low Level (Noise Immunity) (Functional Test)	$V_{IL2}$	-	4(a)	$V_{IL} = 4\text{Vdc}$ $V_{IH} = 11\text{Vdc}$ $V_{DD} = 15\text{Vdc}, V_{SS} = 0\text{Vdc}$ Note 5 (Pins D/F 4-5-6-7-9-10-11-12-13-14) (Pins C 5-6-7-9-11-12-14-15-16-17)	13.5	-	V
	Input Voltage High Level (Noise Immunity) (Functional Test)	$V_{IH2}$			-	1.5		
92	Threshold Voltage N-Channel	$V_{THN}$	-	4(j)	Clock Input at Ground All Other Inputs: $V_{IN} = 5\text{Vdc}$ $V_{DD} = 5\text{Vdc}, I_{SS} = -10\mu\text{A}$ (Pin D/F 8) (Pin C 10)	-0.7	-3.0	V
93	Threshold Voltage P-Channel	$V_{THP}$	-	4(k)	Clock Input at Ground All Other Inputs: $V_{IN} = -5\text{Vdc}$ $V_{SS} = -5\text{Vdc}, I_{DD} = 10\mu\text{A}$ (Pin D/F 16) (Pin C 20)	0.7	3.0	V
94 to 97	Input Clamp Voltage (to $V_{SS}$ )	$V_{IC1}$	-	4(l)	$I_{IN}$ (Under Test) = $-100\mu\text{A}$ $V_{DD} = \text{Open}, V_{SS} = 0\text{Vdc}$ All Other Pins Open (Pins D/F 1-2-3-15) (Pins C 1-2-4-19)	-	-2.0	V
98 to 101	Input Clamp Voltage (to $V_{DD}$ )	$V_{IC2}$	-	4(m)	$V_{IN}$ (Under Test) = $6\text{Vdc}$ $V_{SS} = \text{Open}, R = 30\text{k}\Omega$ (Pins D/F 1-2-3-15) (Pins C 1-2-4-19)	3.0	-	V

**NOTES:** See Page 26.



SCC

ESA/SCC Detail Specification  
No. 9306/026PAGE 24  
ISSUE 3

TABLE 2 - ELECTRICAL MEASUREMENTS AT ROOM TEMPERATURE - a.c. PARAMETERS

NO.	CHARACTERISTICS	SYMBOL	TEST METHOD MIL-STD 883	TEST FIG.	TEST CONDITIONS (PINS UNDER TEST D/F = DIP AND FP C = CCP)	LIMITS		UNIT
						MIN	MAX	
102 to 105	Input Capacitance	$C_{IN}$	3012	4(n)	$V_{IN}$ (Not Under Test) = 0Vdc $V_{DD} = V_{SS} = 0$ Vdc Note 6 (Pins D/F 1-2-3-15) (Pins C 1-2-4-19)	-	7.5	pF
106	Propagation Delay Low to High, (Clock to Serial Output QS)	$t_{PLH1}$	3003	4(o)	$V_{IN}$ (Under Test) = Pulse Generator $V_{IN}$ (All Other Inputs) = 5Vdc $V_{DD} = 5$ Vdc, $V_{SS} = 0$ Vdc Note 7 <u>Pins D/F</u> <u>Pins C</u> 3 to 9              4 to 11	-	550	ns
107	Propagation Delay Low to High, (Clock to Serial Output Q' S)	$t_{PLH2}$	3003	4(o)	$V_{IN}$ (Under Test) = Pulse Generator $V_{IN}$ (All Other Inputs) = 5Vdc $V_{DD} = 5$ Vdc, $V_{SS} = 0$ Vdc Note 7 <u>Pins D/F</u> <u>Pins C</u> 3 to 10              4 to 12	-	550	ns
108	Propagation Delay High to Low, (Clock to Serial Output QS)	$t_{PHL1}$	3003	4(o)	$V_{IN}$ (Under Test) = Pulse Generator $V_{IN}$ (All Other Inputs) = 5Vdc $V_{DD} = 5$ Vdc, $V_{SS} = 0$ Vdc Note 7 <u>Pins D/F</u> <u>Pins C</u> 3 to 9              4 to 11	-	550	ns
109	Propagation Delay High to Low, (Clock to Serial Output Q' S)	$t_{PHL2}$	3003	4(o)	$V_{IN}$ (Under Test) = Pulse Generator $V_{IN}$ (All Other Inputs) = 5Vdc $V_{DD} = 5$ Vdc, $V_{SS} = 0$ Vdc Note 7 <u>Pins D/F</u> <u>Pins C</u> 3 to 10              4 to 12	-	550	ns

**NOTES:** See Page 26.



SCC

ESA/SCC Detail Specification

No. 9306/026

PAGE 25

ISSUE 3

**TABLE 2 - ELECTRICAL MEASUREMENTS AT ROOM TEMPERATURE - a.c. PARAMETERS (CONT'D)**

NO.	CHARACTERISTICS	SYMBOL	TEST METHOD MIL-STD 883	TEST FIG.	TEST CONDITIONS (PINS UNDER TEST D/F = DIP AND FP C = CCP)	LIMITS		UNIT
						MIN	MAX	
110	Propagation Delay High Impedance to Low Output	t <sub>PZL</sub>	3003	4(p)	V <sub>IN</sub> (Enable) = Pulse Generator V <sub>OUT</sub> = 0Vdc V <sub>DD</sub> = 5Vdc, V <sub>SS</sub> = 0Vdc Note 7 <u>Pins D/F</u> <u>Pins C</u> 15 to 4        19 to 5	-	180	ns
111	Propagation Delay Low Output to High Impedance	t <sub>PLZ</sub>	3003	4(p)	V <sub>IN</sub> (Enable) = Pulse Generator V <sub>OUT</sub> = 0Vdc V <sub>DD</sub> = 5Vdc, V <sub>SS</sub> = 0Vdc Note 7 <u>Pins D/F</u> <u>Pins C</u> 15 to 4        19 to 5	-	180	ns
112	Propagation Delay High Impedance to High Output	t <sub>PZH</sub>	3003	4(p)	V <sub>IN</sub> (Enable) = Pulse Generator V <sub>OUT</sub> = 5Vdc V <sub>DD</sub> = 5Vdc, V <sub>SS</sub> = 0Vdc Note 7 <u>Pins D/F</u> <u>Pins C</u> 15 to 4        19 to 5	-	280	ns
113	Propagation Delay High Output to High Impedance	t <sub>PHZ</sub>	3003	4(p)	V <sub>IN</sub> (Enable) = Pulse Generator V <sub>OUT</sub> = 5Vdc V <sub>DD</sub> = 5Vdc, V <sub>SS</sub> = 0Vdc Note 7 <u>Pins D/F</u> <u>Pins C</u> 15 to 4        19 to 5	-	280	ns
114 to 115	Transition Time Low to High	t <sub>TLH</sub>	3004	4(o)	V <sub>IN</sub> (Under Test) = Pulse Generator V <sub>IN</sub> (All Other Inputs) = 5Vdc V <sub>DD</sub> = 5Vdc, V <sub>SS</sub> = 0Vdc Note 7 (Pins D/F 9-10) (Pins C 11-12)	-	150	ns

**NOTES:** See Page 26.



SCC

ESA/SCC Detail Specification  
No. 9306/026

PAGE 26  
ISSUE 3

**TABLE 2 - ELECTRICAL MEASUREMENTS AT ROOM TEMPERATURE - a.c. PARAMETERS (CONT'D)**

NO.	CHARACTERISTICS	SYMBOL	TEST METHOD MIL-STD 883	TEST FIG.	TEST CONDITIONS (PINS UNDER TEST D/F = DIP AND FP C = CCP)	LIMITS		UNIT
						MIN	MAX	
116 to 117	Transition Time High to Low	t <sub>THL</sub>	3004	4(o)	V <sub>IN</sub> (Under Test) = Pulse Generator V <sub>IN</sub> (All Other Inputs) = 5Vdc V <sub>DD</sub> = 5Vdc, V <sub>SS</sub> = 0Vdc Note 7 (Pins D/F 9-10) (Pins C 11-12)	-	150	ns
118	Maximum Clock Input Frequency	f <sub>(CL)</sub>	3004	4(o)	V <sub>IN</sub> (Under Test) = Pulse Generator V <sub>IN</sub> (All Other Inputs) = 5Vdc V <sub>DD</sub> = 5Vdc, V <sub>SS</sub> = 0Vdc Notes 7 and 8 Pins D/F 3 to 9      Pins C 4 to 11	1.25	-	MHz

**NOTES**

1. GO-NO-GO Test, each pattern of Test Table 4(a).  
 $V_{OH} \geq V_{DD} - 0.5\text{Vdc}$     $V_{OL} \leq 0.5\text{Vdc}$
2. Maximum time to output comparator strobe 300 $\mu\text{sec}$ .
3. Apply 9 clock pulses of V<sub>DD</sub> to V<sub>SS</sub> to the Clock Input.
4. Interchange of forcing and measuring function is permitted.
5. This is performed as a Functional Test in which extreme V<sub>IN</sub> conditions are applied and output voltage is measured.
6. Measurement performed on a sample basis, LTPD7 or less, with a Capacitance Bridge connected between each input under test and V<sub>SS</sub>, only for Lots where LAT Level 2 is to be performed. (For LTPD sampling plan, see Annexe I of ESA/SCC 9000).
7. Measurement performed on a sample basis, LTPD7 or less, (see Annexe I of ESA/SCC 9000).
8. A pulse, having the following conditions, shall be applied to the clock input: V<sub>p</sub> = 0Vdc to V<sub>DD</sub> Vdc. Maximum clock frequency f<sub>(CL)</sub> requirement is considered met if proper output state changes occur with the pulse repetition rate set to that given in the "Limits" column.



SCC

ESA/SCC Detail Specification  
No. 9306/026

PAGE 27

ISSUE 3

TABLE 3(a) - ELECTRICAL MEASUREMENTS AT HIGH TEMPERATURE, + 125(+ 0-5) °C

NO.	CHARACTERISTICS	SYMBOL	TEST METHOD MIL-STD 883	TEST FIG.	TEST CONDITIONS (PINS UNDER TEST D/F = DIP AND FP C = CCP)	LIMITS		UNIT
						MIN	MAX	
1	Functional Test	-	-	4(a)	Verify Truth Table without Load. $V_{DD} = 3\text{Vdc}$ , $V_{SS} = 0\text{Vdc}$ Notes 1 and 2	-	-	-
2	Functional Test	-	-	4(a)	Verify Truth Table without Load. $V_{DD} = 15\text{Vdc}$ , $V_{SS} = 0\text{Vdc}$ Notes 1 and 2	-	-	-
3 to 5	Quiescent Current	$I_{DD}$	3005	4(b)	$V_{IL} = 0\text{Vdc}$ , $V_{IH} = 15\text{Vdc}$ $V_{DD} = 15\text{Vdc}$ , $V_{SS} = 0\text{Vdc}$ (Pin D/F 16) (Pin C 20)	-	30	$\mu\text{A}$
6 to 9	Input Current Low Level	$I_{IL}$	3009	4(c)	$V_{IN}$ (Under Test) = $0\text{Vdc}$ $V_{IN}$ (All Other Inputs) = $15\text{Vdc}$ $V_{DD} = 15\text{Vdc}$ , $V_{SS} = 0\text{Vdc}$ (Pins D/F 1-2-3-15) (Pins C 1-2-4-19)	-	-100	nA
10 to 13	Input Current High Level	$I_{IH}$	3010	4(d)	$V_{IN}$ (Under Test) = $15\text{Vdc}$ $V_{IN}$ (All Other Inputs) = $0\text{Vdc}$ $V_{IN} = 0\text{Vdc}$ $V_{DD} = 15\text{Vdc}$ , $V_{SS} = 0\text{Vdc}$ (Pins D/F 1-2-3-15) (Pins C 1-2-4-19)	-	100	nA
14 to 23	Output Voltage Low Level	$V_{OL}$	3007	4(e)	$V_{IN}$ (Data) = $0\text{Vdc}$ Clock = Pulse Generator $V_{IN}$ (All Other Inputs) = $15\text{Vdc}$ $V_{OUT} = \text{Open}$ $V_{DD} = 15\text{Vdc}$ , $V_{SS} = 0\text{Vdc}$ Note 3 (Pins D/F 4-5-6-7-9-10-11-12-13-14) (Pins C 5-6-7-9-11-12-14-15-16-17)	-	0.05	V

NOTES: See Page 26.



SCC

ESA/SCC Detail Specification

No. 9306/026

PAGE 28

ISSUE 3

TABLE 3(a) - ELECTRICAL MEASUREMENTS AT HIGH TEMPERATURE, + 125(+ 0-5) °C (CONT'D)

NO.	CHARACTERISTICS	SYMBOL	TEST METHOD MIL-STD 883	TEST FIG.	TEST CONDITIONS (PINS UNDER TEST D/F = DIP AND FP C = CCP)	LIMITS		UNIT
						MIN	MAX	
24 to 33	Output Voltage Low Level	V <sub>OH</sub>	3006	4(f)	V <sub>IN</sub> (Enable) = 15Vdc Clock = Pulse Generator V <sub>IN</sub> (All Other Inputs) = 15Vdc V <sub>OUT</sub> = Open V <sub>DD</sub> = 15Vdc, V <sub>SS</sub> = 0Vdc Note 3 (Pins D/F 4-5-6-7-9-10-11- 12-13-14) (Pins C 5-6-7-9-11-12-14- 15-16-17)	14.95	-	V
34 to 43	Output Drive Current N-Channel	I <sub>OL1</sub>	-	4(g)	V <sub>IN</sub> (Data) = 0Vdc Clock = Pulse Generator V <sub>IN</sub> (All Other Inputs) = 5Vdc V <sub>OUT</sub> = 0.4Vdc V <sub>DD</sub> = 5Vdc, V <sub>SS</sub> = 0Vdc Notes 3 and 4 (Pins D/F 4-5-6-7-9-10-11- 12-13-14) (Pins C 6-7-9-10-14-15- 16-17-19-20)	0.36	-	mA
44 to 53	Output Drive Current N-Channel	I <sub>OL2</sub>	-	4(g)	V <sub>IN</sub> (Data) = 0Vdc Clock = Pulse Generator V <sub>IN</sub> (All Other Inputs) = 15Vdc V <sub>OUT</sub> = 1.5Vdc V <sub>DD</sub> = 15Vdc, V <sub>SS</sub> = 0Vdc Notes 3 and 4 (Pins D/F 4-5-6-7-9-10-11- 12-13-14) (Pins C 6-7-9-10-14-15- 16-17-19-20)	2.4	-	mA
54 to 63	Output Drive Current P-Channel	I <sub>OH1</sub>	-	4(h)	V <sub>IN</sub> (Enable) = 5Vdc Clock = Pulse Generator V <sub>IN</sub> (All Other Inputs) = 5Vdc V <sub>OUT</sub> = 4.6Vdc V <sub>DD</sub> = 5Vdc, V <sub>SS</sub> = 0Vdc Notes 3 and 4 (Pins D/F 4-5-6-7-9-10-11- 12-13-14) (Pins C 6-7-9-10-14-15- 16-17-19-20)	-0.36	-	mA

**NOTES:** See Page 26.



SCC

ESA/SCC Detail Specification

No. 9306/026

PAGE 29

ISSUE 3

**TABLE 3(a) - ELECTRICAL MEASUREMENTS AT HIGH TEMPERATURE, + 125( + 0-5) °C (CONT'D)**

NO.	CHARACTERISTICS	SYMBOL	TEST METHOD MIL-STD 883	TEST FIG.	TEST CONDITIONS (PINS UNDER TEST D/F = DIP AND FP C = CCP)	LIMITS		UNIT
						MIN	MAX	
64 to 73	Output Drive Current P-Channel	$I_{OH2}$	-	4(h)	$V_{IN}$ (Enable) = 15Vdc Clock = Pulse Generator $V_{IN}$ (All Other Inputs) = 15Vdc $V_{OUT}$ = 13.5Vdc $V_{DD}$ = 15Vdc, $V_{SS}$ = 0Vdc Notes 3 and 4 (Pins D/F 4-5-6-7-9-10-11-12-13-14) (Pins C 6-7-9-10-14-15-16-17-19-20)	-2.4	-	mA
74 to 81	Output Leakage Current Third State (1)	$I_{OZ1}$	-	4(i)	$V_{IN}$ (Strobe and Data) = 15Vdc Clock = Pulse Generator $V_{IN}$ (Enable) = 0Vdc $V_{OUT}$ = 15Vdc $V_{DD}$ = 15Vdc, $V_{SS}$ = 0Vdc (Pins D/F 4-5-6-7-11-12-13-14) (Pins C 5-6-7-9-14-15-16-17)	-	12	$\mu A$
82 to 89	Output Leakage Current Third State (2)	$I_{OZ2}$	-	4(i)	$V_{IN}$ (Strobe and Data) = 15Vdc Clock = Pulse Generator $V_{IN}$ (Enable) = 0Vdc $V_{OUT}$ = 0Vdc $V_{DD}$ = 15Vdc, $V_{SS}$ = 0Vdc (Pins D/F 4-5-6-7-11-12-13-14) (Pins C 5-6-7-9-14-15-16-17)	-	-12	$\mu A$
90	Input Voltage Low Level (Noise Immunity) (Functional Test)	$V_{IL1}$	-	4(a)	$V_{IL}$ = 1.5Vdc $V_{IH}$ = 3.5Vdc $V_{DD}$ = 5Vdc, $V_{SS}$ = 0Vdc Note 5 (Pins D/F 4-5-6-7-9-10-11-12-13-14) (Pins C 5-6-7-9-11-12-14-15-16-17)	4.5	-	V
	Input Voltage High Level (Noise Immunity) (Functional Test)	$V_{IH1}$				-	0.5	

**NOTES:** See Page 26.



SCC

ESA/SCC Detail Specification

No. 9306/026

PAGE 30

ISSUE 3

**TABLE 3(a) - ELECTRICAL MEASUREMENTS AT HIGH TEMPERATURE, +125(+0-5) °C (CONT'D)**

NO.	CHARACTERISTICS	SYMBOL	TEST METHOD MIL-STD 883	TEST FIG.	TEST CONDITIONS (PINS UNDER TEST D/F = DIP AND FP C = CCP)	LIMITS		UNIT
						MIN	MAX	
91	Input Voltage Low Level (Noise Immunity) (Functional Test)	$V_{IL2}$	-	4(a)	$V_{IL} = 4\text{Vdc}$ $V_{IH} = 11\text{Vdc}$ $V_{DD} = 15\text{Vdc}, V_{SS} = 0\text{Vdc}$ Note 5 (Pins D/F 4-5-6-7-9-10-11-12-13-14) (Pins C 5-6-7-9-11-12-14-15-16-17)	13.5	-	V
	Input Voltage High Level (Noise Immunity) (Functional Test)	$V_{IH2}$			-	1.5		
92	Threshold Voltage N-Channel	$V_{THN}$	-	4(j)	Clock Input at Ground All Other Inputs: $V_{IN} = 5\text{Vdc}$ $V_{DD} = 5\text{Vdc}, I_{SS} = -10\mu\text{A}$ (Pin D/F 8) (Pin C 10)	-0.3	-3.5	V
93	Threshold Voltage P-Channel	$V_{THP}$	-	4(k)	Clock Input at Ground All Other Inputs: $V_{IN} = -5\text{Vdc}$ $V_{SS} = -5\text{Vdc}, I_{DD} = 10\mu\text{A}$ (Pin D/F 16) (Pin C 20)	0.3	3.5	V

**NOTES:** See Page 26.



SCC

ESA/SCC Detail Specification

No. 9306/026

PAGE 31

ISSUE 3

**TABLE 3(b) - ELECTRICAL MEASUREMENTS AT LOW TEMPERATURE, -55( + 5-0) °C**

NO.	CHARACTERISTICS	SYMBOL	TEST METHOD MIL-STD 883	TEST FIG.	TEST CONDITIONS (PINS UNDER TEST D/F = DIP AND FP C = CCP)	LIMITS		UNIT
						MIN	MAX	
1	Functional Test	-	-	4(a)	Verify Truth Table without Load. $V_{DD} = 3Vdc$ , $V_{SS} = 0Vdc$ Notes 1 and 2	-	-	-
2	Functional Test	-	-	4(a)	Verify Truth Table without Load. $V_{DD} = 15Vdc$ , $V_{SS} = 0Vdc$ Notes 1 and 2	-	-	-
3 to 5	Quiescent Current	$I_{DD}$	3005	4(b)	$V_{IL} = 0Vdc$ , $V_{IH} = 15Vdc$ $V_{DD} = 15Vdc$ , $V_{SS} = 0Vdc$ (Pin D/F 16) (Pin C 20)	-	1.0	$\mu A$
6 to 9	Input Current Low Level	$I_{IL}$	3009	4(c)	$V_{IN}$ (Under Test) = 0Vdc $V_{IN}$ (All Other Inputs) = 15Vdc $V_{DD} = 15Vdc$ , $V_{SS} = 0Vdc$ (Pins D/F 1-2-3-15) (Pins C 1-2-4-19)	-	-50	nA
10 to 13	Input Current High Level	$I_{IH}$	3010	4(d)	$V_{IN}$ (Under Test) = 15Vdc $V_{IN}$ (All Other Inputs) = 0Vdc $V_{DD} = 15Vdc$ , $V_{SS} = 0Vdc$ (Pins D/F 1-2-3-15) (Pins C 1-2-4-19)	-	50	nA
14 to 23	Output Voltage Low Level	$V_{OL}$	3007	4(e)	$V_{IN}$ (Data) = 0Vdc Clock = Pulse Generator $V_{IN}$ (All Other Inputs) = 15Vdc $V_{OUT}$ = Open $V_{DD} = 15Vdc$ , $V_{SS} = 0Vdc$ Note 3 (Pins D/F 4-5-6-7-9-10-11-12-13-14) (Pins C 5-6-7-9-11-12-14-15-16-17)	-	0.05	V

**NOTES:** See Page 26.



SCC

ESA/SCC Detail Specification  
No. 9306/026PAGE 32  
ISSUE 3

TABLE 3(b) - ELECTRICAL MEASUREMENTS AT LOW TEMPERATURE, -55(+5-0) °C (CONT'D)

NO.	CHARACTERISTICS	SYMBOL	TEST METHOD MIL-STD 883	TEST FIG.	TEST CONDITIONS (PINS UNDER TEST D/F = DIP AND FP C = CCP)	LIMITS		UNIT
						MIN	MAX	
24 to 33	Output Voltage Low Level	$V_{OH}$	3006	4(f)	$V_{IN}$ (Enable) = 15Vdc $V_{IN}$ (All Other Inputs) = 15Vdc $V_{OUT}$ = Open $V_{DD} = 15\text{Vdc}$ , $V_{SS} = 0\text{Vdc}$ Note 3 (Pins D/F 4-5-6-7-9-10-11-12-13-14) (Pins C 5-6-7-9-11-12-14-15-16-17)	14.95	-	V
34 to 43	Output Drive Current N-Channel	$I_{OL1}$	-	4(g)	$V_{IN}$ (Data) = 0Vdc $V_{IN}$ (All Other Inputs) = 5Vdc $V_{OUT} = 0.4\text{Vdc}$ $V_{DD} = 5\text{Vdc}$ , $V_{SS} = 0\text{Vdc}$ Notes 3 and 4 (Pins D/F 4-5-6-7-9-10-11-12-13-14) (Pins C 6-7-9-10-14-15-16-17-19-20)	0.64	-	mA
44 to 53	Output Drive Current N-Channel	$I_{OL2}$	-	4(g)	$V_{IN}$ (Data) = 0Vdc $V_{IN}$ (All Other Inputs) = 15Vdc $V_{OUT} = 1.5\text{Vdc}$ $V_{DD} = 15\text{Vdc}$ , $V_{SS} = 0\text{Vdc}$ Notes 3 and 4 (Pins D/F 4-5-6-7-9-10-11-12-13-14) (Pins C 6-7-9-10-14-15-16-17-19-20)	4.2	-	mA
54 to 63	Output Drive Current P-Channel	$I_{OH1}$	-	4(h)	$V_{IN}$ (Enable) = 5Vdc $V_{IN}$ (All Other Inputs) = 5Vdc $V_{OUT} = 4.6\text{Vdc}$ $V_{DD} = 5\text{Vdc}$ , $V_{SS} = 0\text{Vdc}$ Notes 3 and 4 (Pins D/F 4-5-6-7-9-10-11-12-13-14) (Pins C 6-7-9-10-14-15-16-17-19-20)	-0.64	-	mA

**NOTES:** See Page 26.



SCC

ESA/SCC Detail Specification

No. 9306/026

PAGE 33

ISSUE 3

TABLE 3(b) - ELECTRICAL MEASUREMENTS AT LOW TEMPERATURE, -55(+5-0) °C (CONT'D)

NO.	CHARACTERISTICS	SYMBOL	TEST METHOD MIL-STD 883	TEST FIG.	TEST CONDITIONS (PINS UNDER TEST D/F = DIP AND FP C = CCP)	LIMITS		UNIT
						MIN	MAX	
64 to 73	Output Drive Current P-Channel	$I_{OH2}$	-	4(h)	$V_{IN}$ (Enable) = 15Vdc Clock = Pulse Generator $V_{IN}$ (All Other Inputs) = 15Vdc $V_{OUT}$ = 13.5Vdc $V_{DD}$ = 15Vdc, $V_{SS}$ = 0Vdc Notes 3 and 4 (Pins D/F 4-5-6-7-9-10-11-12-13-14) (Pins C 6-7-9-10-14-15-16-17-19-20)	-4.2	-	mA
74 to 81	Output Leakage Current Third State (1)	$I_{OZ1}$	-	4(i)	$V_{IN}$ (Strobe and Data) = 15Vdc Clock = Pulse Generator $V_{IN}$ (Enable) = 0Vdc $V_{OUT}$ = 15Vdc $V_{DD}$ = 15Vdc, $V_{SS}$ = 0Vdc (Pins D/F 4-5-6-7-11-12-13-14) (Pins C 5-6-7-9-14-15-16-17)	-	0.4	$\mu A$
82 to 89	Output Leakage Current Third State (2)	$I_{OZ2}$	-	4(i)	$V_{IN}$ (Strobe and Data) = 15Vdc Clock = Pulse Generator $V_{IN}$ (Enable) = 0Vdc $V_{OUT}$ = 0Vdc $V_{DD}$ = 15Vdc, $V_{SS}$ = 0Vdc (Pins D/F 4-5-6-7-11-12-13-14) (Pins C 5-6-7-9-14-15-16-17)	-	-0.4	$\mu A$
90	Input Voltage Low Level (Noise Immunity) (Functional Test)	$V_{IL1}$	-	4(a)	$V_{IL}$ = 1.5Vdc $V_{IH}$ = 3.5Vdc $V_{DD}$ = 5Vdc, $V_{SS}$ = 0Vdc Note 5 (Pins D/F 4-5-6-7-9-10-11-12-13-14) (Pins C 5-6-7-9-11-12-14-15-16-17)	4.5	-	V
	Input Voltage High Level (Noise Immunity) (Functional Test)	$V_{IH1}$			-	0.5		

NOTES: See Page 26.



SCC

ESA/SCC Detail Specification  
No. 9306/026

PAGE 34

ISSUE 3

TABLE 3(b) - ELECTRICAL MEASUREMENTS AT LOW TEMPERATURE, -55( + 5-0) °C (CONT'D)

NO.	CHARACTERISTICS	SYMBOL	TEST METHOD MIL-STD 883	TEST FIG.	TEST CONDITIONS (PINS UNDER TEST D/F = DIP AND FP C = CCP)	LIMITS		UNIT
						MIN	MAX	
91	Input Voltage Low Level (Noise Immunity) (Functional Test)	$V_{IL2}$	-	4(a)	$V_{IL} = 4\text{Vdc}$ $V_{IH} = 11\text{Vdc}$ $V_{DD} = 15\text{Vdc}, V_{SS} = 0\text{Vdc}$ Note 5 (Pins D/F 4-5-6-7-9-10-11-12-13-14) (Pins C 5-6-7-9-11-12-14-15-16-17)	13.5	-	V
	Input Voltage High Level (Noise Immunity) (Functional Test)	$V_{IH2}$			-	1.5		
92	Threshold Voltage N-Channel	$V_{THN}$	-	4(j)	Clock Input at Ground All Other Inputs: $V_{IN} = 5\text{Vdc}$ $V_{DD} = 5\text{Vdc}, I_{SS} = -10\mu\text{A}$ (Pin D/F 8) (Pin C 10)	-0.7	-3.5	V
93	Threshold Voltage P-Channel	$V_{THP}$	-	4(k)	Clock Input at Ground All Other Inputs: $V_{IN} = -5\text{Vdc}$ $V_{SS} = -5\text{Vdc}, I_{DD} = 10\mu\text{A}$ (Pin D/F 16) (Pin C 20)	0.7	3.5	V

**NOTES:** See Page 26.



SCC

ESA/SCC Detail Specification  
No. 9306/026PAGE 35  
ISSUE 3**FIGURE 4 - CIRCUITS FOR ELECTRICAL MEASUREMENTS****FIGURE 4(a) - FUNCTIONAL TEST TABLE**

PATTERN NO.	PIN NUMBERS															D.C. SUPPLY	
	1	2	3	4	5	6	7	9	10	11	12	13	14	15			
1	0	0	0	X	X	X	X	X	X	X	X	X	X	X	1	0	VDD
2	0	0	1	X	X	X	X	X	X	X	X	X	X	X	1		
3	0	0	0	X	X	X	X	X	X	X	X	X	X	X	1		
4	0	0	1	X	X	X	X	X	X	X	X	X	X	X	1		
5	0	0	0	X	X	X	X	X	X	X	X	X	X	X	1		
6	0	0	1	X	X	X	X	X	X	X	X	X	X	X	1		
7	0	0	0	X	X	X	X	X	X	X	X	X	X	X	1		
8	0	0	1	X	X	X	X	X	X	X	X	X	X	X	1		
9	0	0	0	X	X	X	X	X	X	X	X	X	X	X	1		
10	0	0	1	X	X	X	X	X	X	X	X	X	X	X	1		
11	0	0	0	X	X	X	X	X	X	X	X	X	X	X	1		
12	0	0	1	X	X	X	X	X	X	X	X	X	X	X	1		
13	0	0	0	X	X	X	X	X	X	X	X	X	X	X	1		
14	0	0	1	X	X	X	X	X	X	X	X	X	X	X	1		
15	0	0	0	X	X	X	X	X	X	X	X	X	X	X	1		
16	1	0	1	X	X	X	X	X	X	X	X	X	X	X	1		
17	1	0	0	0	0	0	0	0	0	0	0	0	0	0	0	1	
18	1	1	0	0	0	0	0	0	0	0	0	0	0	0	0	1	
19	1	1	1	1	0	0	0	0	0	0	0	0	0	0	0	1	
20	1	0	0	1	0	0	0	0	0	0	0	0	0	0	0	1	
21	1	0	1	0	1	0	0	0	0	0	0	0	0	0	0	1	
22	1	1	0	0	1	0	0	0	0	0	0	0	0	0	0	1	
23	1	1	1	1	0	1	0	0	0	0	0	0	0	0	0	1	
24	1	0	0	1	0	1	0	0	0	0	0	0	0	0	0	1	
25	1	0	1	0	1	0	1	0	0	0	0	0	0	0	0	1	
26	1	1	0	0	1	0	1	0	0	0	0	0	0	0	0	1	
27	1	1	1	1	0	1	0	0	0	0	0	0	0	0	1	1	
28	1	0	0	1	0	1	0	0	0	0	0	0	0	0	1	1	
29	1	0	1	0	1	0	1	0	0	0	0	0	0	1	0	1	
30	1	1	0	0	1	0	1	0	0	0	0	0	0	1	0	1	
31	1	1	1	1	0	1	0	0	0	0	0	0	1	0	1	1	
32	1	0	0	1	0	1	0	0	0	0	0	1	0	1	1		
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35	0	1	1	0	1	0	1	0	1	1	1	0	1	0	1	1	
36	1	1	1	1	0	1	0	0	1	0	1	0	1	0	1	1	
37	1	1	0	1	0	1	0	0	0	0	1	0	1	0	1	1	
38	1	1	1	1	1	0	1	1	0	1	0	1	0	1	0	1	
39	1	1	0	1	1	0	1	1	1	1	1	0	1	0	1	0	
40	1	1	1	1	1	1	0	0	1	0	1	0	1	0	1	1	
41	0	1	0	1	1	1	0	0	0	0	1	0	1	0	1	1	
42	0	1	1	1	1	1	0	1	0	0	0	1	0	1	1		
43	0	1	0	1	1	1	0	1	1	0	1	0	1	0	1	1	

**NOTES**

1. Figure 4(a) illustrates one series of Test Patterns. Any other pattern series must be agreed with the Qualifying Space Agency and shall be included as an Appendix.
2. Logic Level Definitions:  $1 = V_{IH} = V_{DD}$ ,  $0 = V_{IL} = V_{SS}$ , X = Don't Care.



SCC

ESA/SCC Detail Specification

No. 9306/026

PAGE 36

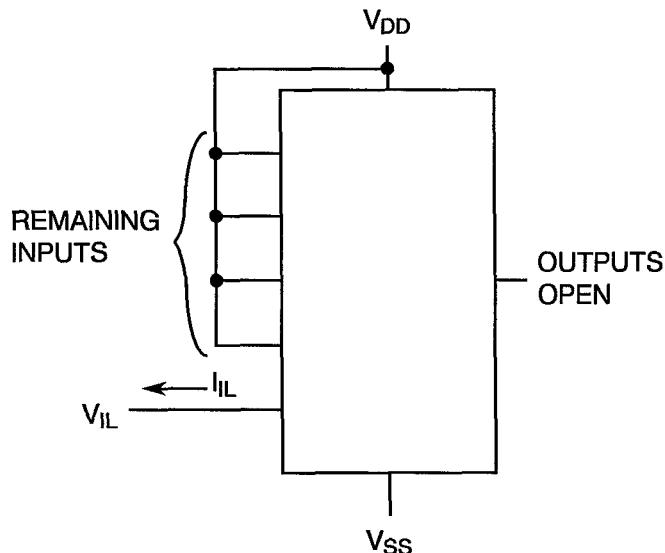
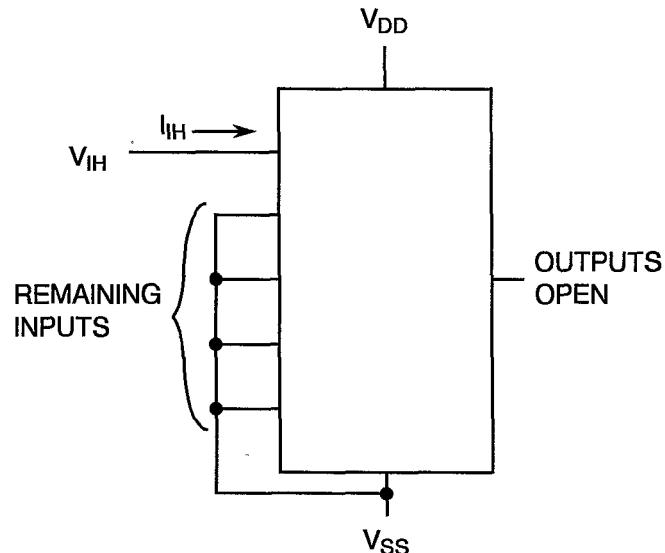
ISSUE 3

**FIGURE 4 - CIRCUITS FOR ELECTRICAL MEASUREMENTS (CONT'D)****FIGURE 4(b) - QUIESCENT CURRENT TEST TABLE**

PATTERN NO.	I <sub>DD</sub> TEST NO.	PIN NUMBERS													D.C. SUPPLY		
		1	2	3	4	5	6	7	9	10	11	12	13	14	15	8	16
1		1	0	0											1	0	V <sub>DD</sub>
2		1	0	0											1		
3		1	0	1											O/C		
4		1	0	0												1	
5		1	0	1												1	
6		1	0	0												1	
7		1	0	1												1	
8		1	0	0												1	
9		1	0	1												1	
10		1	0	0												1	
11		1	0	1												1	
12		1	0	0												1	
13		1	0	1												1	
14		1	0	0												1	
15		1	0	1												1	
16		1	0	0												1	
17		1	0	1												1	
18		1	0	0												1	
19	1	1	0	1												1	
20	2	1	0	0												1	
21		0	0	0												1	
22		1	1	0												1	
23		1	1	0												1	
24		1	1	1												1	
25		1	1	0												1	
26		1	1	1												1	
27		1	1	0												1	
28		1	1	1												1	
29		1	1	0												1	
30		1	1	1												1	
31		1	1	0												1	
32		1	1	1												1	
33		1	1	0												1	
34		1	1	1												1	
35		1	1	0												1	
36		1	1	1												1	
37		1	1	0												1	
38		1	1	1												1	
39		1	1	0												1	
40		1	1	1												1	
41	3	1	1	0												1	

**NOTES**

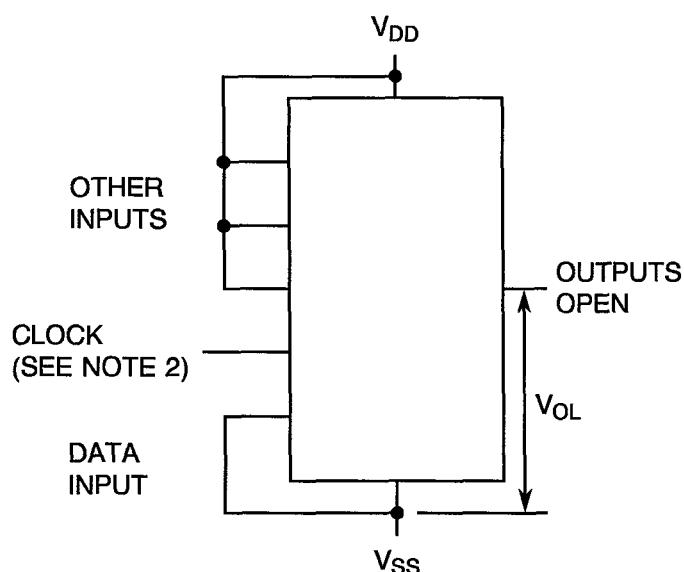
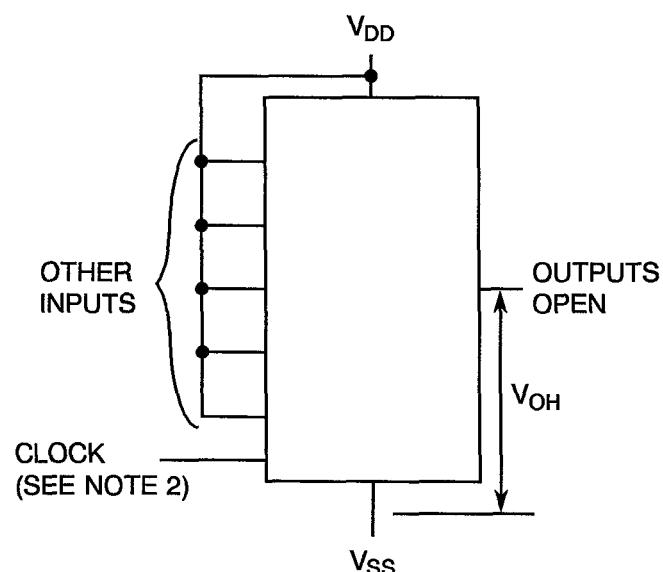
- Figure 4(b) illustrates one series of Test Patterns. Any other pattern series must be agreed with the Qualifying Space Agency and shall be included as an Appendix.
- Logic Level Definitions: 1 = V<sub>IH</sub> = V<sub>DD</sub>, 0 = V<sub>IL</sub> = V<sub>SS</sub>, O/C = Open Circuit.

**FIGURE 4 - CIRCUITS FOR ELECTRICAL MEASUREMENTS (CONTINUED)****FIGURE 4(c) - LOW LEVEL INPUT CURRENT****FIGURE 4(d) - HIGH LEVEL INPUT CURRENT****NOTES**

1. Each input to be tested separately.

**NOTES**

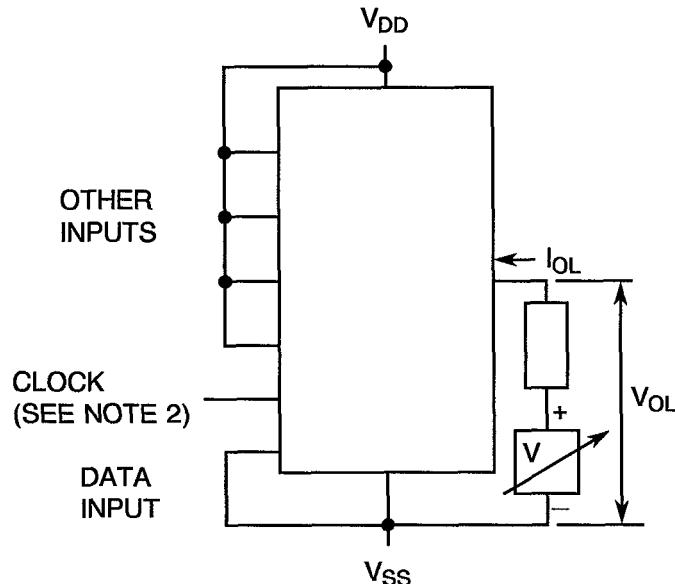
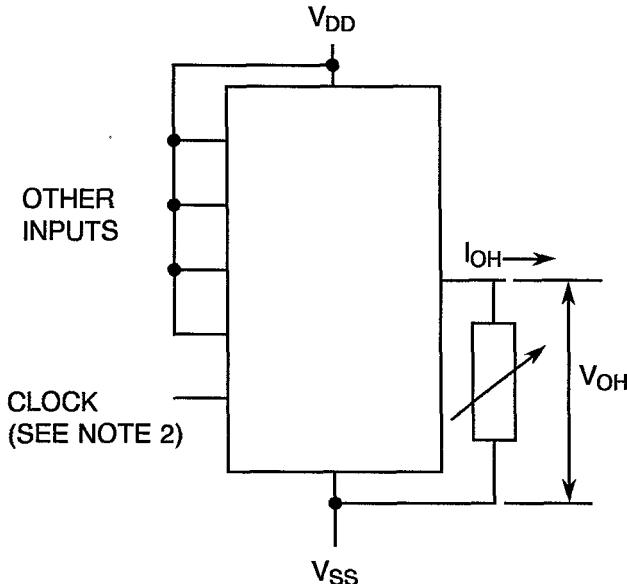
1. Each input to be tested separately.

**FIGURE 4(e) - LOW LEVEL OUTPUT VOLTAGE****FIGURE 4(f) - HIGH LEVEL OUTPUT VOLTAGE****NOTES**

1. Each output to be tested separately.
2. Nine clock pulses of  $V_{DD}$  to  $V_{SS}$  to be applied.

**NOTES**

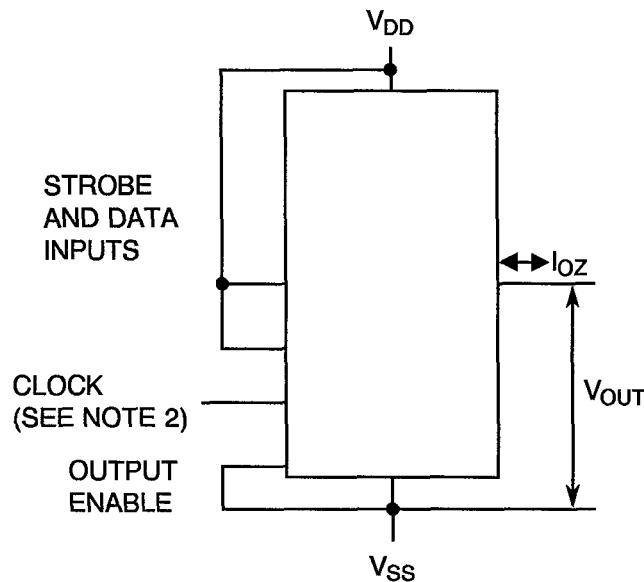
1. Each output to be tested separately.
2. Nine clock pulses of  $V_{DD}$  to  $V_{SS}$  to be applied.

**FIGURE 4 - CIRCUITS FOR ELECTRICAL MEASUREMENTS (CONTINUED)****FIGURE 4(g) - LOW LEVEL OUTPUT CURRENT****FIGURE 4(h) - HIGH LEVEL OUTPUT CURRENT****NOTES**

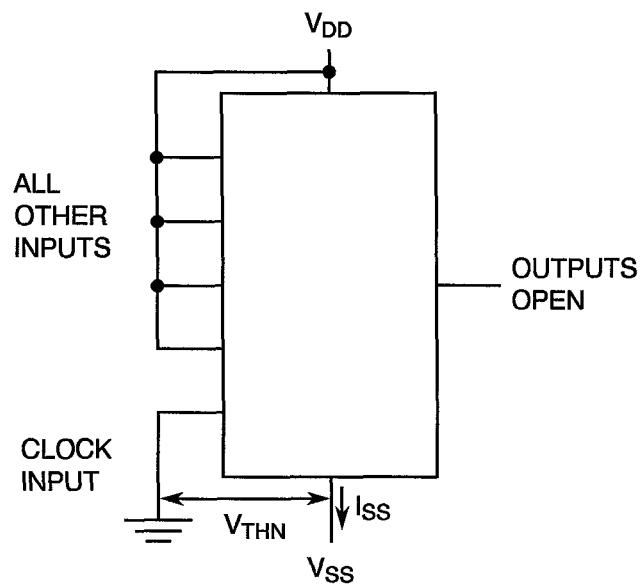
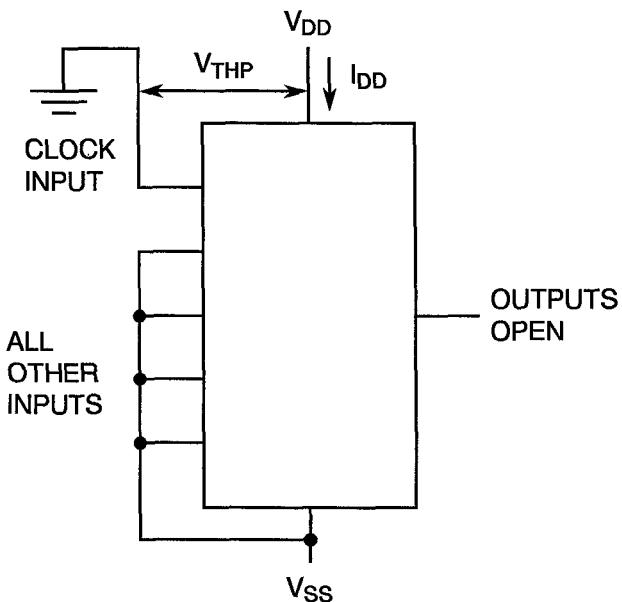
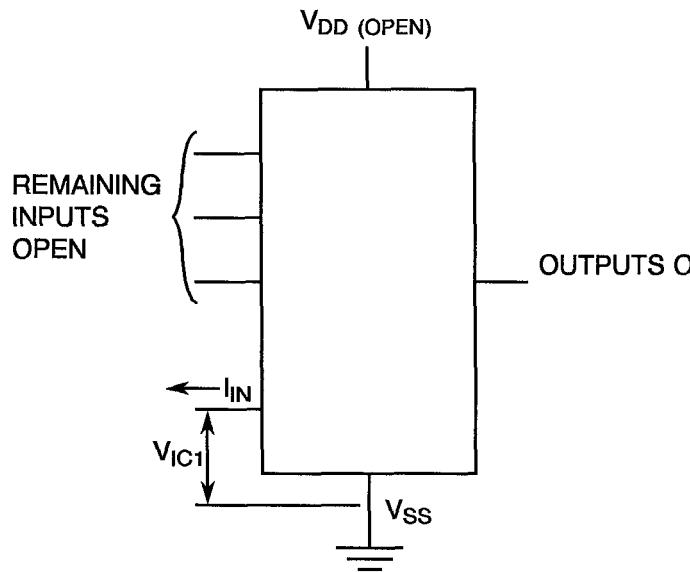
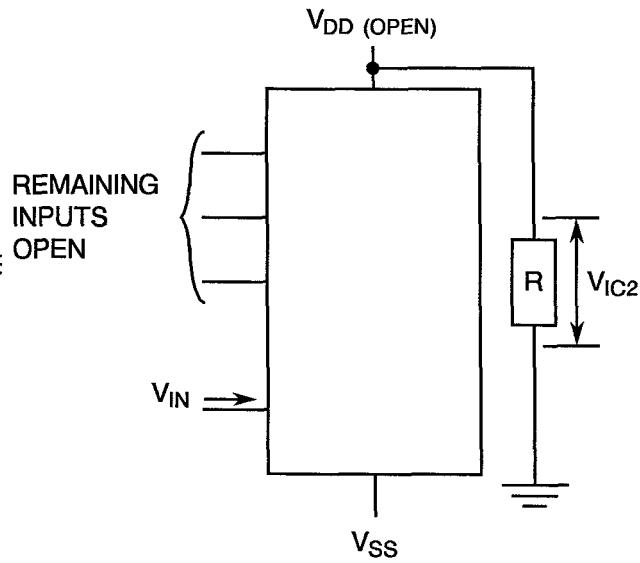
1. Each output to be tested separately.
2. Nine clock pulses of  $V_{DD}$  to  $V_{SS}$  to be applied.

**NOTES**

1. Each output to be tested separately.
2. Nine clock pulses of  $V_{DD}$  to  $V_{SS}$  to be applied.

**FIGURE 4(i) - OUTPUT LEAKAGE CURRENT THIRD STATE****NOTES**

1. Each output to be tested separately.
2. Nine clock pulses of  $V_{DD}$  to  $V_{SS}$  to be applied.

**FIGURE 4 - CIRCUITS FOR ELECTRICAL MEASUREMENTS (CONTINUED)**FIGURE 4(i) - THRESHOLD VOLTAGE N-CHANNELFIGURE 4(k) - THRESHOLD VOLTAGE P-CHANNELFIGURE 4(l) - INPUT CLAMP VOLTAGE ( $V_{SS}$ )FIGURE 4(m) - INPUT CLAMP VOLTAGE ( $V_{DD}$ )**NOTES**

1. Each input to be tested separately.

**NOTES**

1. Each input to be tested separately.



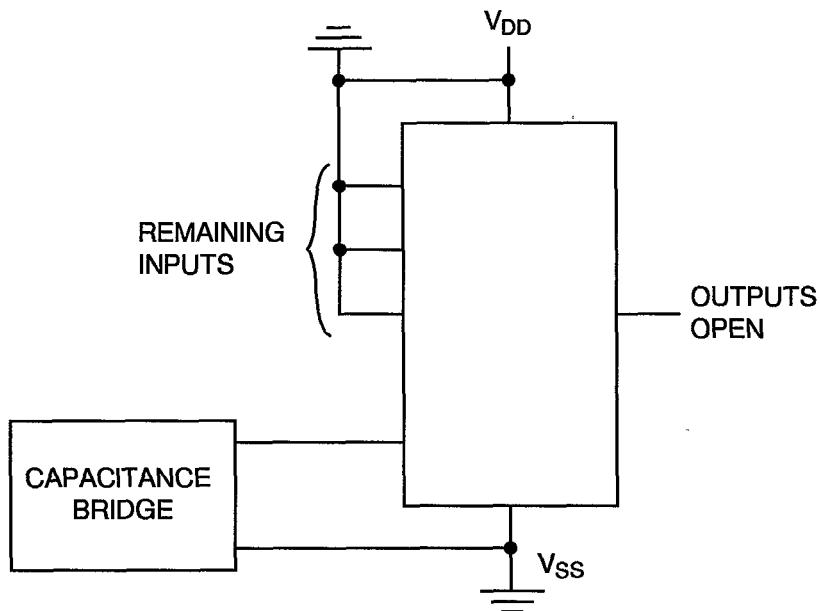
**SCC**

ESA/SCC Detail Specification  
No. 9306/026

PAGE 40  
ISSUE 3

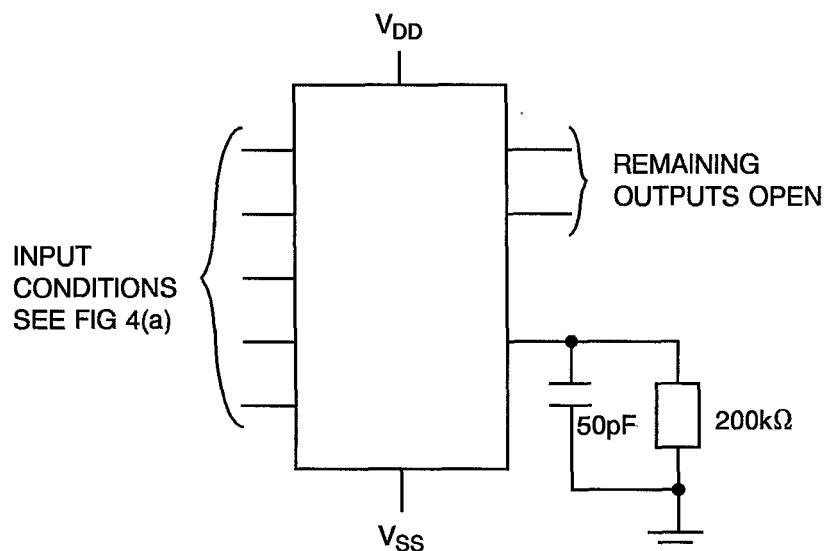
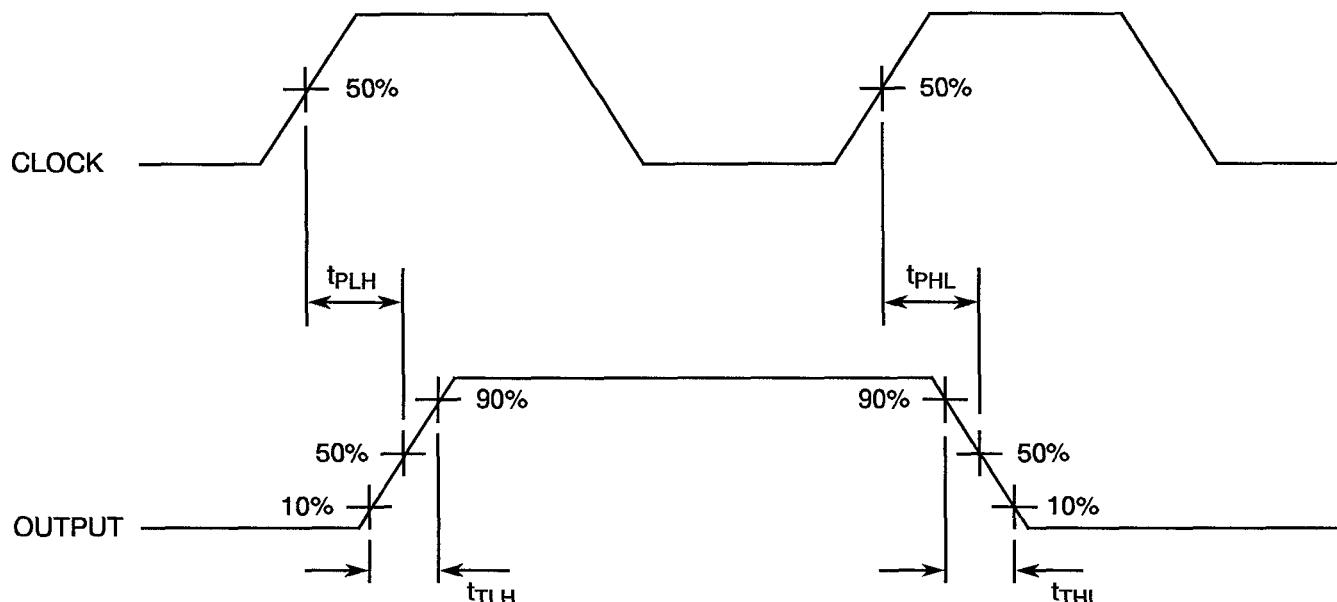
**FIGURE 4 - CIRCUITS FOR ELECTRICAL MEASUREMENTS (CONTINUED)**

**FIGURE 4(n) - INPUT CAPACITANCE**

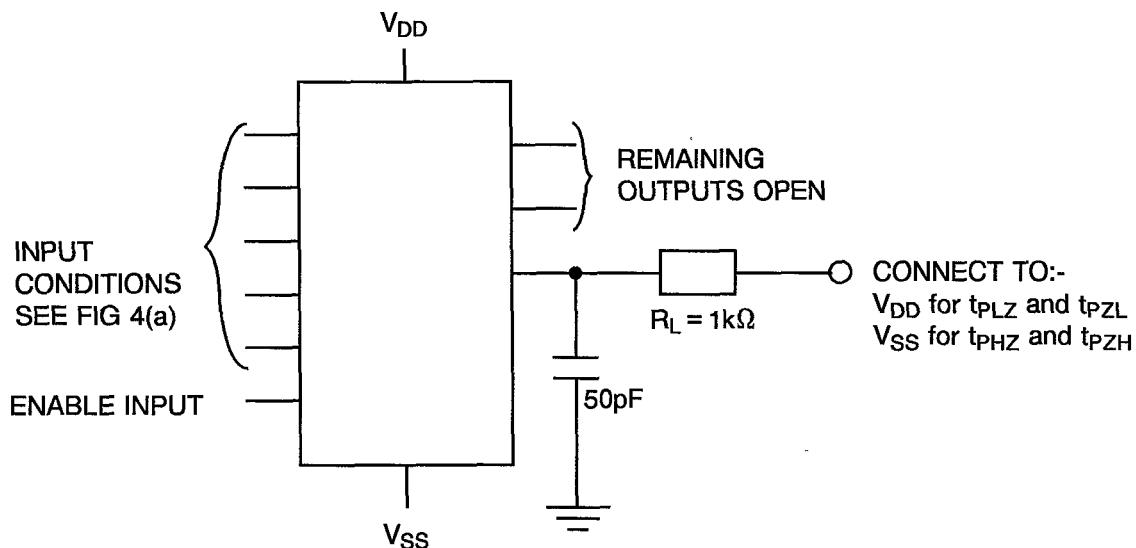
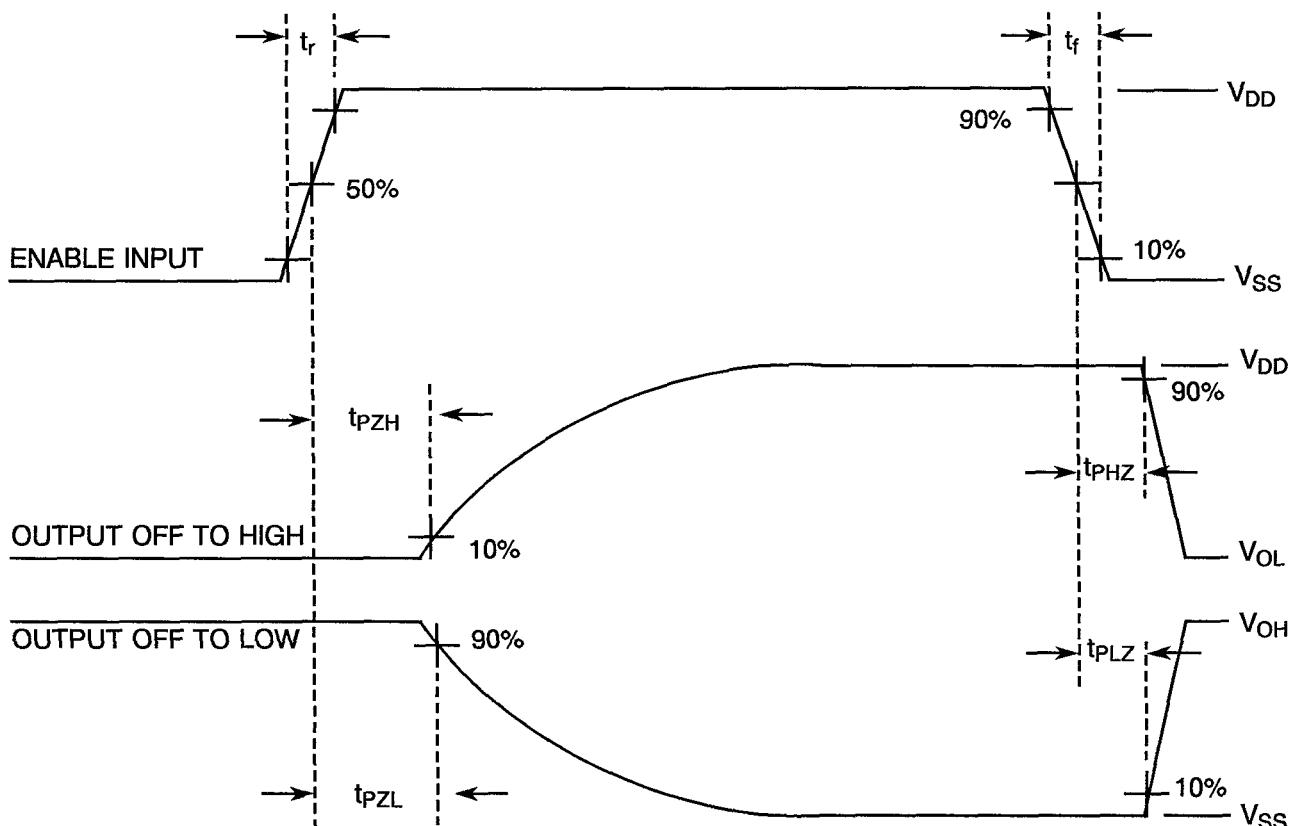


**NOTES**

1. Each input to be tested separately.
2.  $f = 100\text{kHz}$  to  $1\text{MHz}$ .

**FIGURE 4 - CIRCUITS FOR ELECTRICAL MEASUREMENTS (CONTINUED)****FIGURE 4(o) - PROPAGATION DELAY AND TRANSITION TIME****VOLTAGE WAVEFORMS****NOTES**

1. Pulse Generator -  $V_P = 0$  to  $V_{DD}$ ,  $t_r$  and  $t_f \leq 15\text{ns}$ ,  $f = 500\text{kHz}$ .

**FIGURE 4 - CIRCUITS FOR ELECTRICAL MEASUREMENTS (CONTINUED)****FIGURE 4(p) - PROPAGATION DELAY, ENABLE TO OUTPUT****VOLTAGE WAVEFORMS****NOTES**

1. Pulse Generator -  $V_P = 0$  to  $V_{DD}$ ,  $t_r$  and  $t_f \leq 15\text{ns}$ ,  $f = 500\text{kHz}$ .



SCC

ESA/SCC Detail Specification

No. 9306/026

PAGE 43

ISSUE 3

**TABLE 4 - PARAMETER DRIFT VALUES**

NO.	CHARACTERISTICS	SYMBOL	SPEC. AND/OR TEST METHOD	TEST CONDITIONS	CHANGE LIMITS ( $\Delta$ )	UNIT
3 to 5	Quiescent Current	$I_{DD}$	As per Table 2	As per Table 2	$\pm 150$	nA
34 to 43	Output Drive Current N-Channel	$I_{OL1}$	As per Table 2	As per Table 2	$\pm 15$ (1)	%
54 to 63	Output Drive Current P-Channel	$I_{OH1}$	As per Table 2	As per Table 2	$\pm 15$ (1)	%
74 to 81	Output Leakage Current Third State (1)	$I_{OZ1}$	As per Table 2	As per Table 2	$\pm 60$	nA
82 to 89	Output Leakage Current Third State (2)	$I_{OZ2}$	As per Table 2	As per Table 2	$\pm 60$	nA
92	Threshold Voltage N-Channel	$V_{THN}$	As per Table 2	As per Table 2	$\pm 0.3$	V
93	Threshold Voltage P-Channel	$V_{THP}$	As per Table 2	As per Table 2	$\pm 0.3$	V

**NOTES**

1. Percentage of limit value if voltage is the measurement function.



SCC

ESA/SCC Detail Specification  
No. 9306/026PAGE 44  
ISSUE 3**TABLE 5(a) - CONDITIONS FOR BURN-IN HIGH TEMPERATURE REVERSE BIAS, N-CHANNELS**

NO.	CHARACTERISTICS	SYMBOL	CONDITION	UNIT
1	Ambient Temperature	T <sub>amb</sub>	+ 125 ( + 0-5)	°C
2	Outputs - (Pins D/F 4-5-6-7-9-10-11-12-13-14) (Pins C 5-6-7-9-11-12-14-15-16-17)	V <sub>OUT</sub>	Open	-
3	Input - (Pin D/F 3) (Pin C 4)	V <sub>IN</sub>	Ground	Vdc
4	Input - (Pins D/F 1-2-15) (Pins C 1-2-19)	V <sub>IN</sub>	V <sub>DD</sub>	Vdc
5	Positive Supply Voltage (Pin D/F 16) (Pin C 20)	V <sub>DD</sub>	15	Vdc
6	Negative Supply Voltage (Pin D/F 8) (Pin C 10)	V <sub>SS</sub>	Ground	Vdc

**NOTES**

1. Input Load = Protection Resistor = 2kΩ minimum to 47kΩ maximum.

**TABLE 5(b) - CONDITIONS FOR BURN-IN HIGH TEMPERATURE REVERSE BIAS, P-CHANNELS**

NO.	CHARACTERISTICS	SYMBOL	CONDITION	UNIT
1	Ambient Temperature	T <sub>amb</sub>	+ 125 ( + 0-5)	°C
2	Outputs - (Pins D/F 4-5-6-7-9-10-11-12-13-14) (Pins C 5-6-7-9-11-12-14-15-16-17)	V <sub>OUT</sub>	Open	-
3	Input - (Pin D/F 3) (Pin C 4)	V <sub>IN</sub>	V <sub>DD</sub>	Vdc
4	Input - (Pin D/F 1-2-15) (Pin C 1-2-19)	V <sub>IN</sub>	Ground	Vdc
5	Positive Supply Voltage (Pin D/F 16) (Pin C 20)	V <sub>DD</sub>	15	Vdc
6	Negative Supply Voltage (Pin D/F 8) (Pin C 10)	V <sub>SS</sub>	Ground	Vdc

**NOTES**

1. Input Load = Protection Resistor = 2kΩ minimum to 47kΩ maximum.

**SCC**

ESA/SCC Detail Specification

No. 9306/026

PAGE 45

ISSUE 3

**TABLE 5(c) - CONDITIONS FOR BURN-IN DYNAMIC**

NO.	CHARACTERISTICS	SYMBOL	CONDITIONS	UNIT
1	Ambient Temperature	$T_{amb}$	+125 (+0-5)	°C
2	Outputs - (Pins D/F 4-5-6-7-9-10-11-12-13-14) (Pins C 5-6-7-9-11-12-14-15-16-17)	$V_{OUT}$	$V_{DD}/2$	Vdc
3	Inputs - (Pins D/F 1-15) (Pins C 1-19)	$V_{IN}$	$V_{DD}$	Vdc
4	Input - (Pin D/F 2) (Pin C 2)	$V_{IN}$	$V_{GEN2}$	Vac
5	Input - (Pin D/F 3) (Pin C 4)	$V_{IN}$	$V_{GEN1}$	Vac
6	Pulse Voltage	$V_{GEN}$	0 to $V_{DD}$	Vac
7	Pulse Frequency Square Wave	$f_{GEN1}$	50k 50% duty cycle	Hz
8	Pulse Frequency Square Wave	$f_{GEN2}$	25k 50% duty cycle	Hz
9	Positive Supply Voltage (Pin D/F 16) (Pin C 20)	$V_{DD}$	15	Vdc
10	Negative Supply Voltage (Pin D/F 8) (Pin C 10)	$V_{SS}$	Ground	Vdc

**NOTES**

1. Input Load = Output Load =  $2k\Omega$  minimum to  $47k\Omega$  maximum.



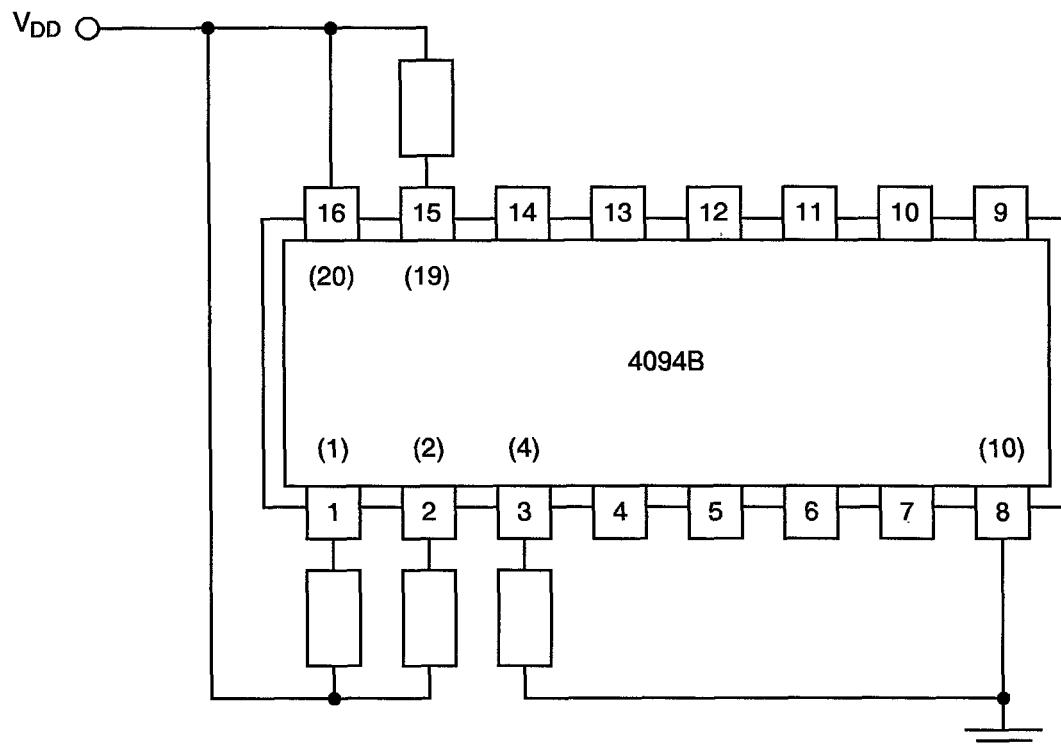
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ESA/SCC Detail Specification

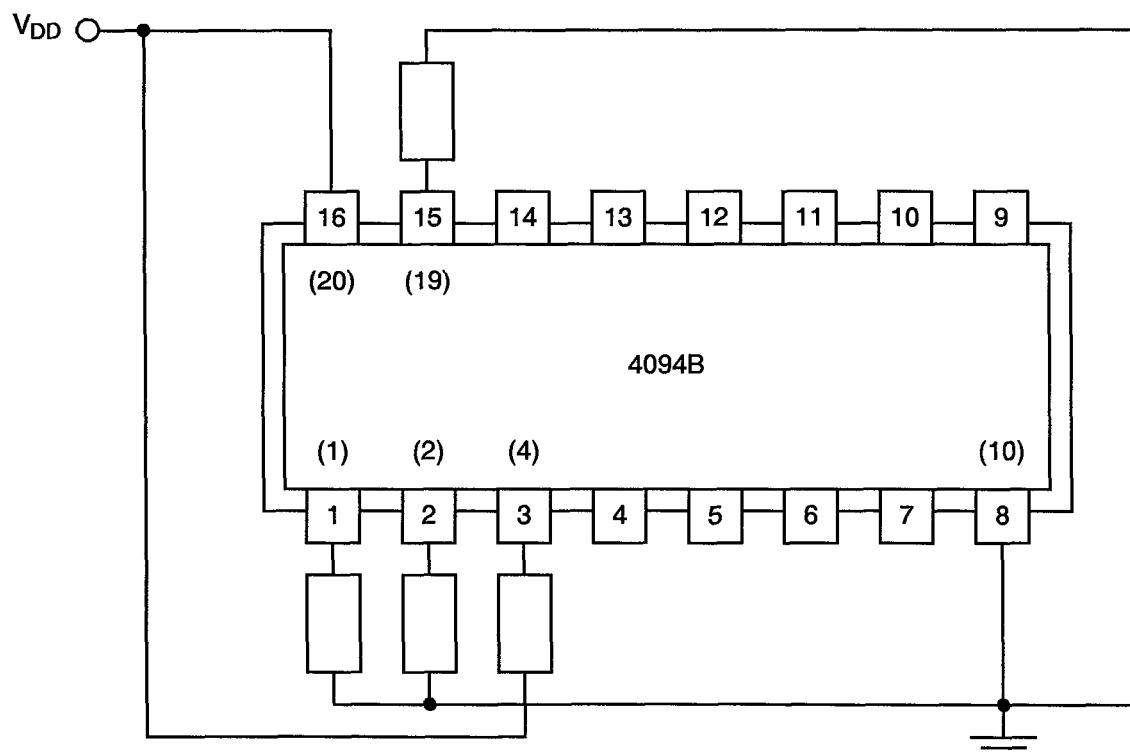
No. 9306/026

PAGE 46

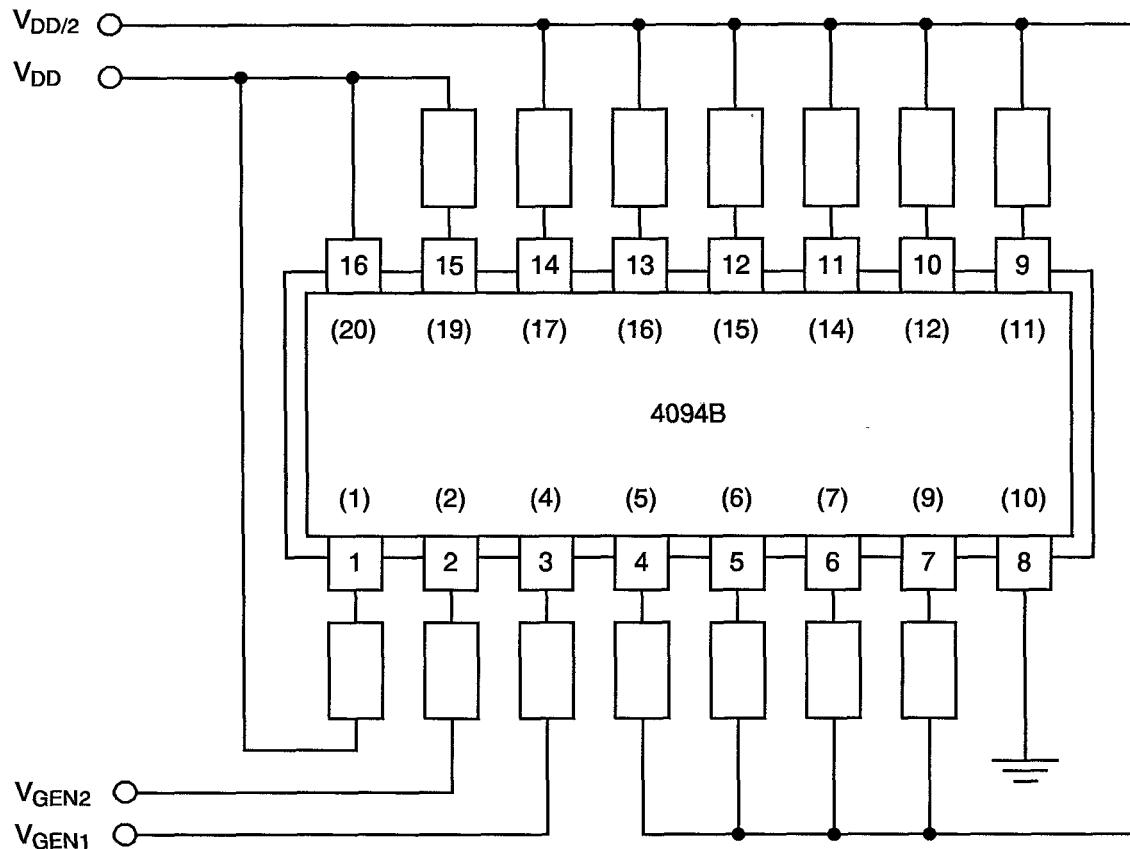
ISSUE 3

**FIGURE 5(a) - ELECTRICAL CIRCUIT FOR BURN-IN HIGH TEMPERATURE REVERSE BIAS, N-CHANNELS****NOTES**

1. Pin numbers in parenthesis are for the chip carrier package.

**FIGURE 5(b) - ELECTRICAL CIRCUIT FOR BURN-IN HIGH TEMPERATURE REVERSE BIAS, P-CHANNELS****NOTES**

1. Pin numbers in parenthesis are for the chip carrier package.

**SCC**ESA/SCC Detail Specification  
No. 9306/026PAGE 47  
ISSUE 3**FIGURE 5(c) - ELECTRICAL CIRCUIT FOR BURN-IN DYNAMIC****NOTES**

1. Pin numbers in parenthesis are for the chip carrier package.



4.8 ENVIRONMENTAL AND ENDURANCE TESTS (CHARTS IV AND V OF ESA/SCC GENERIC SPECIFICATION NO. 9000)

4.8.1 Electrical Measurements on Completion of Environmental Tests

The parameters to be measured on completion of environmental tests are scheduled in Table 6. Unless otherwise stated, the measurements shall be performed at  $T_{amb} = +22 \pm 3^{\circ}\text{C}$ .

4.8.2 Electrical Measurements at Intermediate Points during Endurance Tests

The parameters to be measured at intermediate points during endurance tests are as scheduled in Table 6 of this specification.

4.8.3 Electrical Measurements on Completion of Endurance Tests

The parameters to be measured on completion of endurance testing are as scheduled in Table 6 of this specification. Unless otherwise stated, the measurements shall be performed at  $T_{amb} = +22 \pm 3^{\circ}\text{C}$ .

4.8.4 Conditions for Operating Life Test

The requirements for operating life testing are specified in Section 9 of ESA/SCC Generic Specification No. 9000. The conditions for operating life testing shall be as specified in Table 5(c) of this specification.

4.8.5 Electrical Circuits for Operating Life Tests

Circuits for use in performing the operating life test are shown in Figure 5(c) of this specification.

4.8.6 Conditions for High Temperature Storage Test

The requirements for the high temperature storage test are specified in ESA/SCC Generic Specification No. 9000. The temperature to be applied shall be the maximum storage temperature specified in Table 1(b) of this specification.



SCC

ESA/SCC Detail Specification

No. 9306/026

PAGE 49

ISSUE 3

**TABLE 6 - ELECTRICAL MEASUREMENTS ON COMPLETION OF ENVIRONMENTAL TESTS AND AT  
INTERMEDIATE POINTS AND ON COMPLETION OF ENDURANCE TESTING**

NO.	CHARACTERISTICS	SYMBOL	SPEC. AND/OR TEST METHOD	TEST CONDITIONS	CHANGE LIMITS (Δ)			UNIT
						MIN	MAX	
1	Functional Test	-	As per Table 2	As per Table 2	-	-	-	-
3 to 5	Quiescent Current	I <sub>DD</sub>	As per Table 2	As per Table 2	± 150	-	-	nA
6 to 9	Input Current Low Level	I <sub>IL</sub>	As per Table 2	As per Table 2	-	-	-50	nA
10 to 13	Input Current High Level	I <sub>IH</sub>	As per Table 2	As per Table 2	-	-	50	nA
14 to 23	Output Voltage Low Level	V <sub>OL</sub>	As per Table 2	As per Table 2	-	-	0.05	V
24 to 33	Output Voltage High Level	V <sub>OH</sub>	As per Table 2	As per Table 2	-	14.95	-	V
34 to 43	Output Drive Current N-Channel	I <sub>OL1</sub>	As per Table 2	As per Table 2	± 15 (1)	-	-	%
44 to 53	Output Drive Current N-Channel	I <sub>OL2</sub>	As per Table 2	As per Table 2	± 15 (1)	-	-	%
54 to 63	Output Drive Current P-Channel	I <sub>OH1</sub>	As per Table 2	As per Table 2	± 15 (1)	-	-	%
64 to 73	Output Drive Current P-Channel	I <sub>OH2</sub>	As per Table 2	As per Table 2	± 15 (1)	-	-	%
74 to 81	Output Leakage Current Third State (1)	I <sub>OZ1</sub>	As per Table 2	As per Table 2	± 60	-	-	nA
82 to 89	Output Leakage Current Third State (2)	I <sub>OZ2</sub>	As per Table 2	As per Table 2	± 60	-	-	nA

**NOTES**

1. Percentage of limit value if voltage is the measurement function.

**SCC**

ESA/SCC Detail Specification

No. 9306/026

PAGE 50

ISSUE 3

**TABLE 6 - ELECTRICAL MEASUREMENTS ON COMPLETION OF ENVIRONMENTAL TESTS AND AT  
INTERMEDIATE POINTS AND ON COMPLETION OF ENDURANCE TESTING**

NO.	CHARACTERISTICS	SYMBOL	SPEC. AND/OR TEST METHOD	TEST CONDITIONS	CHANGE LIMITS (Δ)			UNIT
						MIN	MAX	
90	Input Voltage Low Level (Noise Immunity) (Functional Test)	$V_{IL1}$	As per Table 2	As per Table 2	-	4.5	-	V
	Input Voltage High Level (Noise Immunity) (Functional Test)	$V_{IH1}$			-	-	0.5	
92	Threshold Voltage N-Channel	$V_{THN}$	As per Table 2	As per Table 2	$\pm 0.3$	-	-	V
93	Threshold Voltage P-Channel	$V_{THP}$	As per Table 2	As per Table 2	$\pm 0.3$	-	-	V

**SCC**

ESA/SCC Detail Specification

No. 9306/026

PAGE 51

ISSUE 3

**APPENDIX 'A'**

Page 1 of 1

**AGREED DEVIATIONS FOR STMICROELECTRONICS (F)**

ITEMS AFFECTED	DESCRIPTION OF DEVIATION
Para. 4.2.3	Para. 9.23, High Temperature Reverse Bias Burn-in: The temperature limits of MIL-STD-883, Para. 4.5.8(c) may be used.  Para. 9.24, Power Burn-in: The temperature limits of MIL-STD-883, Para. 4.5.8(c) may be used.
Para. 4.2.4	Para. 9.21.1, Operating Life during Qualification Testing: The temperature limits of MIL-STD-883, Para. 4.5.8(c) may be used.
Para. 4.2.5	Para. 9.21.2, Operating Life during Lot Acceptance Testing: The temperature limits of MIL-STD-883, Para. 4.5.8(c) may be used.